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## **A measurement method for lossy capacitive relative humidity sensors based on a direct sensor-to-microcontroller interface circuit**

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### **Abstract**

A new time-domain measurement method for determining the capacitance and resistance values of lossy relative humidity capacitive sensors is presented. The method is based on a direct sensor-to-microcontroller interface for microcontrollers with internal analog comparators and timers. The interface circuit consists only of four reference resistors (two reference resistors if a microcontroller includes a voltage reference source), a given sensor and a microcontroller. A systematic error correction algorithm based on a correction dictionary and the  $M$ -multiple measurement approach are also proposed in the paper. Experimental investigations were carried out using a prototype device based on an 8-bit ATXmega32A4 microcontroller. The experimental research confirmed that the relative errors of measurement of capacitance introduced by the interface circuit are less than 0.71% (for capacitance values 100 – 286 pF), and the relative errors of measurement of resistance are less than 0.74% (for resistance values 1 – 10 M $\Omega$ ).

**Keywords:** microcontroller interfacing, capacitive sensors, analog comparators, time-domain measurement

## 1. Introduction

Capacitive sensors, which are widely used for the measurement of many physical and chemical quantities, can be modelled with lossless capacitance  $C_x$  (the perfect capacitive sensor) or modelled with shunt resistance  $R_x$  in parallel with  $C_x$  (for a lossy capacitive sensor). In the first case, inter alia, these are humidity sensors [1–5], pressure sensors [6,7], position sensors [8], surface-force sensors [9], carbon dioxide sensors [10,11], sensors used to measure the flow of fluids [12] and flour biomass materials [13] through pipelines, and sensors for monitoring the level of liquids [14], as well as the water content in oil [14,15], and soil moisture content [16].

The second group, that is, the lossy capacitive sensors, includes sensors, e.g. to measure the conductivity of NaCl solutions [17], to assess the degradation of the quality of frying oil [18] and permittivity values of edible oil [19], humidity sensors [20,21] and humidity sensors subjected to condensation [22]. For these sensors  $R_x$  can play an important role. This value is usually not constant [23], but it can change with the measurand, depends on environmental factors (such as temperature, condensation and pollution) and drifts with time. Consequently, the effects of  $R_x$  must be corrected at electronics level or software level.

For these sensors, various interface circuits have been proposed in the literature. For example, in [24] the interface circuit is based on a modified De-Sauty active bridge, in [17] this system is based on a real-dual-frequency method, in [18] it is based on the conversion of impedance to voltage and phase shift, in [25] it is built with a dual-slope capacitance-to-digital converter with a special clock source, in [19] it is based on the measurement of the quadrature and in-phase components of the signal, in [26] the interface consists mainly of the modified Martin relaxation oscillator, a multiplexer and a microcontroller, in [20] it uses a relaxation oscillator and a new capacitance-to-voltage converter, and in [21] a modified dual-slope conversion scheme is proposed. These interface circuits have several analogue active components, e.g. operational amplifiers (they often require their own supply voltages) between the sensor and a processing and control unit (e.g. a microcontroller) and use sinusoidal excitation for the sensor. The advantage of these solutions is high measuring accuracy. Unfortunately, they are characterized by high circuit complexity and costs, which disqualifies them in many sensor applications, where the key factors are low costs, small energy consumption and small dimensions.

Nowadays, capacitive sensors, as well as other types, are increasingly being designed as smart sensors. They consist of an analogue part, which contains a given sensor and conditioning circuits, and a digital part responsible for collecting and processing the measurement data, controlling the system and communication with the environment (all of these tasks can be performed by a microcontroller). Smart sensors can be one of many components of a system, or they can work as independent devices, e.g. as nodes of a wireless sensor network. In this case, they should be as

small and simple as possible to reduce their dimensions and cost, and they should be energy-efficient — they are often battery powered or can acquire energy from the environment based on an energy harvesting technique.

These requirements are met by sensor interface circuits based on the concept of the sensor-to-microcontroller interface [5,22,27,28]. In this case, a microcontroller generates the stimulation signal for the sensor and measures signal parameters of its response without using any active analogue circuits. The interface circuit for a lossy capacitive humidity sensor proposed in [22] consists of only a few discrete elements: the sensor ( $C_x$  in parallel with  $R_x$ ), a calibration capacitor  $C_c$ , and two resistors,  $R_i$  and  $R_d$ . The method takes into account a stray capacitance  $C_{s1}$  between a pin of the microcontroller and ground. The determination of the capacitance  $C_x$  and parasitic conductance  $G_x$  ( $1/R_x$ ) values of the sensor is based on four measurements of discharging times of the  $(R_d \parallel R_x)(C_x + C_{s1})$ ,  $R_d(C_c + C_{s1})$ ,  $R_d C_{s1}$ , and  $R_x(C_x + C_{s1})$  circuits by the internal timer of the microcontroller.

However, as proposed in [27, 28] the interface circuit can be further simplified by using the internal analogue comparator (AC) of a microcontroller, which is implemented in almost all currently produced 8-bit and especially 32-bit microcontrollers. Based on this approach, a new time-domain measurement method for lossy capacitive sensors was elaborated. In this paper, a version of a grounded (one electrode of the sensor is connected to GND of the interface circuit) lossy capacitive sensor utilising the above method is proposed and analysed. This method was designed and tested for humidity sensors not distant from the system. The concept of the method is derived from the method described in [27]. Based on this, the following new solutions have been proposed:

- A new structure of the interface circuit. The interface circuit consists of only two reference resistors,  $R_{r1}$  and  $R_{r2}$ , and of course the sensor (Fig. 1). The use of resistors as reference elements is an important advantage of the method, because they are characterised by high performance precision and low temperature coefficient of resistance (e.g. typically  $50 \cdot 10^{-6}/^{\circ}\text{C}$ ).
- The determination of the  $C_x$  and  $R_x$  values of the lossy capacitive sensor based on a new measurement procedure. It consists of only two measurements of discharging times  $t_1$  and  $t_2$  of the  $(R_{r1} \parallel R_x)C_x$  and  $(R_{r2} \parallel R_x)C_x$  circuits by the timer controlled by the AC, both built into the microcontroller.
- An implementation of the measurement procedure in the software of an 8-bit microcontroller.
- The dynamic correction algorithm of systematic errors, based on a correction dictionary, which is implemented in the software of the microcontroller.
- The graphic approach to systematic error correction.

It should be emphasized that the interface circuit occupies only three pins of the microcontroller (five pins if we use a resistive divider consisting of  $R_1$  and  $R_2$  (Fig. 1) as the threshold voltage for the AC). This follows from the fact that the same pin, Pin 3, is used to generate the stimulation when charging the interface circuit, and to monitor the voltage level on the sensor during its discharge.

Furthermore, it should be also emphasised that the hardware configuration of the interface circuit is backwards compatible with methods developed for inductive, resistive, and perfect capacitive sensors [27–30]. Therefore, to adapt the system back to such sensors, it is enough to replace the software with the software developed for earlier methods, which is an advantage from a practical point of view.

To analyse and experimentally verify the utility of the proposed measurement method and the interface circuit for grounded lossy capacitive sensors, a shunt resistance  $R_x$  was modelled by a set of resistors with resistance values from a range specified in [22], where the P14 Rapid sensor [31] under condensation effects is presented, and a capacitance  $C_x$  by the set of capacitors with capacitance values from a typical range specified in [22] and in [5], where two relative humidity sensors [32,33] are accurately characterised.

## 2. Description of the method

### 2.1. The operating principle

The proposed direct sensor-to-microcontroller interface circuit for grounded lossy capacitive sensors is shown in Fig. 1. The sensor is modelled by the equivalent circuit  $R_x \parallel C_x$ , with  $R_{r1}$  and  $R_{r2}$  are reference resistors. Additionally, if the microcontroller does not have an internal voltage reference source (e.g. a digital to analogue converter (DAC)), we have to use a resistive divider consisting of  $R_1$  and  $R_2$ . The operating principle of the circuit in Fig. 1, that is, the measurement procedure, consists of four steps as shown in Fig. 2:

- Two charging steps (step I, and step III), in which  $C_x$  is charged to the high output pin voltage  $V_{in}$  ( $V_{in} \approx V_{cc}$  — the supply voltage) via Pin 3 set as an output pin for a time interval longer than  $5R_{pin}C_x$  ( $R_{pin}$  is the Pin 3 output resistance,  $R_{pin} \ll R_{r1} < R_{r2}$ , and also  $R_{pin} \ll R_x$ ).
- Two discharging steps, in which  $C_x$  is discharged to the voltage level  $v_1$  via  $R_{r1} \parallel R_x$  (step II), and next via  $R_{r2} \parallel R_x$  (step IV). In this case Pin 3 is set as input pin internally connected to the AC input.

The states of pins 1, 2 and 3 for all steps are summarised in Table 1.

Table 1. State of pins 1, 2 and 3 and resulting discharging times  $t_1$  and  $t_2$ .

| Steps  | Pin 1 | Pin 2 | Pin 3 | Measured time   |
|--|-------|-------|-------|---|
| I (charging)                                 | '1'   | '1'   | '1'   | -   |
| II (discharging via $R_{r1} \parallel R_x$ ) | '0'   | HZ    | HZ    | $t_1 = -\ln(v_1/V_{in}) \cdot R_{r1} \parallel R_x \cdot C_x$ |
| III (charging)                               | '1'   | '1'   | '1'   | -   |
| IV (discharging via $R_{r2} \parallel R_x$ ) | HZ    | '0'   | HZ    | $t_2 = -\ln(v_1/V_{in}) \cdot R_{r2} \parallel R_x \cdot C_x$ |

where: '1' — output pin with a digital '1' (with an analogue output voltage  $V_{in}$ ),

'0' — output pin with a digital '0' (with an analogue output voltage 0 V),

HZ — high-impedance input pin.

During the charging steps, all circuit capacitances (sensor capacitance, capacitances of microcontroller pins, and parasitic capacitances of the circuit) are always charged to  $V_{in}$ , which ensures the same initial conditions for all measurements.

The measurement of the time  $t_k$  ( $k = 1, 2$ ) is as follows. Immediately after pin reconfiguration (Pin  $k$  is set to '0', other pins to HZ), the embedded timer starts, and  $C_x$  is discharged towards ground through resistance  $R_{rk} \parallel R_x$ . Then, when the discharging exponential signal  $v_{out}$  at Pin 3 (Fig. 1 and Fig. 2) reaches the threshold voltage  $v_1$  of the AC, the timer stops.

According to Table 1, the discharging times  $t_1$  and  $t_2$  depend on  $v_1$  and  $V_{in}$ , which can drift, for example, with temperature and/or time. However, as proven in [27] thanks to the use of the ratio  $\alpha = v_1/V_{in}$ , the drifts are auto-calibrated by the interface circuit itself, and  $\alpha$  is independent of the supply voltage  $V_{cc}$  of the microcontroller.

## 2.2. The algorithm of the measurement procedure

The software implementing the measurement procedure was written in ANSI C for a prototype of a complete solution of a compact smart sensor (Fig. 3) based on an 8-bit ATXmega32A4 microcontroller [33,34] dedicated for grounded lossy capacitive sensors. The microcontroller runs on a crystal oscillator with  $f_{clk} = 16$  MHz ( $t_{clk} = 62.5$  ns) and is powered by  $V_{cc} = 3.3$  V. The 16-bit timer TC0 is controlled via the Event System by the AC (AC0). The threshold voltage  $v_1$  is set by the internal DAC B with the voltage reference equal to  $V_{cc}$ .

The flowchart of the algorithm of the measurement procedure is presented in Fig. 4. The algorithm is implemented in two code sections: the main function section and the interrupt services section, and in the configuration of peripheral devices of the microcontroller forming the time measurement block cooperating with the voltage reference block (Fig. 3). The code in the main

section of the measurement function enables the DAC and the AC, sets  $v_1$  at the output of DAC, and next  $k$ -times performs the following steps:

- It sets high level at outputs pins PC0, PC1 and PA1 (steps I and III) to charge the interface circuit.
- It reconfigures the PA1 pin as an input of the AC, sets low level at the pin PC( $k - 1$ ) and starts timer TC0 in Normal Mode (steps II and IV). Also, flag *end\_conv* used to synchronize the software and hardware, is set. Next, we wait for completion of the measurement of time  $t_k$  by testing flag *end\_conv*. When the AC detects the voltage  $v_{out}$  value achieves the value of voltage  $v_1$ , it generates an event, which saves the current value of the timer to the capture register of channel A. In turn, this event generates an interrupt. As a result, the measured time  $t_k$  is saved and flag *end\_conv* is cleared - causing the transition to the main function code. After that, the timer TC0 is stopped.

Finally the code turns off the time measurement and the voltage reference blocks.

The code of the measurement function occupies only 464 Bytes of the program memory of the microcontroller, and the function responsible for configuration of peripheral devices of the microcontroller takes only 138 Bytes (AVR/GNU C Compiler 4.8.1 was used). It should be mentioned that thanks to the use of the Event System the time  $t_k$  is extended only by  $6 \cdot t_{clk}$  exactly and it can be corrected by software. It results from the fact that  $2 \cdot t_{clk}$  are need to run the TC0 timer (sts instruction [34, page 431]), an event lasts for  $1 \cdot t_{clk}$  [34, page 75], and the propagation delay of the AC in the LP mode is 175 ns [35, page 66], which is almost  $3 \cdot t_{clk}$ .

### 2.3. Circuit analysis

The formula for voltage response  $v_{out}(t)$  during the discharging stages (steps II and IV in Fig. 2) of the ideal interface circuit in the time domain has the form:

$$v_{out}(t) = V_{in} \cdot e^{\frac{-t}{R_x \parallel R_{rk} \cdot C_x}} \quad \text{for } k = 1, 2. \quad (1)$$

When the signal  $v_{out}(t)$  reaches the value of  $v_1$ , the time  $t_k$  is measured. Then:

$$v_1 = V_{in} \cdot e^{\frac{-t_1}{R_x \parallel R_{r1} \cdot C_x}} \quad \text{and} \quad v_1 = V_{in} \cdot e^{\frac{-t_2}{R_x \parallel R_{r2} \cdot C_x}} \quad (2)$$

Equating formulae (2), we obtain the equation:

$$\frac{t_1}{R_x \parallel R_{r1}} = \frac{t_2}{R_x \parallel R_{r2}} \quad (3)$$

From (3), we can determine the formula for  $R_x$ :

$$R_x = \frac{R_{r1} \cdot R_{r2} \cdot (t_2 - t_1)}{R_{r2} \cdot t_1 - R_{r1} \cdot t_2} \quad (4)$$

If we assume that  $\xi = R_{r2}/R_{r1}$ , we can write the final version of the formula for  $R_x$ :

$$R_x = R_{r2} \frac{(t_2 - t_1)}{\xi \cdot t_1 - t_2} \quad (5)$$

From (5), we can see that  $R_x$  depends on the constant circuit parameters  $R_{r2}$  and  $\xi$  and two measured values  $t_1$  and  $t_2$ .

Based on the second formula of (2) and  $\alpha = v_1/V_{in}$ , we can write that:

$$\alpha = \frac{v_1}{V_{in}} = e^{\frac{-t_2}{R_x \parallel R_{r2} \cdot C_x}} \quad (6)$$

From (6), we can derive the formula for  $C_x$ :

$$C_x = \frac{-(R_{r2} - R_{r1})}{R_{r1} \cdot R_{r2} \cdot \ln \alpha} \cdot \frac{t_1 \cdot t_2}{t_2 - t_1} \quad (7)$$

In the similar way as before, we can assume that:

$$\gamma = \frac{-(R_{r2} - R_{r1})}{R_{r1} \cdot R_{r2} \cdot \ln \alpha} \quad (8)$$

Which gives the final formula for  $C_x$ :

$$C_x = \gamma \cdot \frac{t_1 \cdot t_2}{t_2 - t_1} \quad (9)$$

In this case, coefficient  $\gamma$  is also the constant circuit parameter.

Parameters  $R_{r2}$ ,  $\xi$  and  $\gamma$  characterise the configuration of the interface circuit and can be determined only once during the design of the electronic system. Thus, they are constant for a given interface configuration, and they can be constants in the program of the microcontroller. Thanks to this, calculations of  $R_x$  and  $C_x$  based on (5) and (9) are simple.

#### 2.4. Determination of the $\alpha$ coefficient

Determination of the  $\alpha$  parameter and also values of reference resistors  $R_{r1}$  and  $R_{r2}$  are shown for an example of a prototype of a compact smart sensor presented in Fig. 3. The value ranges for

$C_x$  and  $R_x$  are as follows [5,22]:  $C_x \in \langle C_{x,\min}; C_{x,\max} \rangle$ ,  $R_x \in \langle R_{x,\min}; R_{x,\max} \rangle$ , where  $C_{x,\min} = 100$  pF,  $C_{x,\max} = 286$  pF,  $R_{x,\min} = 1$  M $\Omega$ , and  $R_{x,\max} = 10$  M $\Omega$ .

The coefficient  $\alpha = v_1/V_{in}$  ( $0 < \alpha < 1$ ) should be such that the maximum possible relative uncertainty (error) [27]  $dC_x(\alpha)$  of the determination of the values of  $C_x$  with respect to this coefficient is as small as possible. We can also see from Table 1 that the smaller  $\alpha$ , the greater  $t_1$  and  $t_2$ , and thus the smaller the effect of the discretisation error on the measurement results.

Based on the theory presented in [27], we can write that:

$$dC_x(\alpha) = \frac{\partial C_x(\alpha)}{\partial \alpha} \cdot \frac{1}{C_x(\alpha)} = \frac{\Delta \alpha}{\alpha \cdot \ln \alpha} \quad (10)$$

The component  $\Delta \alpha = \Delta c_{DAC} / 2^N$  represents the integral and differential non-linearity  $\Delta c_{DAC}$  of setting the value  $c_{DAC}$  on the DAC, where  $N = 12$  [35, page 66]. It should be mentioned that  $\Delta \alpha$  and  $\alpha = c_{DAC} / 2^N$  are constant for a given microcontroller and they are not sensitive to temperature changes [27]. A graph of  $dC_x(\alpha)$  for  $\Delta \alpha = 6$  LSB is shown in Fig. 5. As can be seen, the values of  $dC_x(\alpha)$  are minimal for  $\alpha$  between 0.2 and 0.5. Hence,  $\alpha = 0.2002$  was chosen, which corresponds to  $c_{DAC} = 820$ .

In the case of using a resistive divider as the threshold voltage source of the AC, we suggest the following resistance values:  $R_1 = 33$  k $\Omega$ , and  $R_2 = 130$  k $\Omega$ , which results in  $\alpha = 0.2025$ . Resistors  $R_1$  and  $R_2$  must have the same temperature coefficient of resistance so that  $\alpha$  is not sensitive to temperature changes of these resistors. The accuracy of the  $\alpha$  setting, i.e. the uncertainty  $d\alpha(R_1, R_2)$  of determining this value, depends as follows on the tolerance  $\delta R$  of resistors  $R_1$  and  $R_2$ :  $d\alpha(R_1, R_2) \approx 0.23 \cdot \delta R$ . Thus it is enough for the resistors to have a tolerance of 0.1%, then  $d\alpha(R_1, R_2)$  is 0.023%.

## 2.5. Determination of the values of reference resistors $R_{r1}$ and $R_{r2}$

If we assume that  $R_{r1} < R_{r2}$ , then  $t_1 < t_2$ . If we also assume that  $t_2 < t_{2,\max}$  (where:  $t_{2,\max} = t_{clk} \cdot 2^N$ , and  $N = 16$ ), that is, we do not want the timer to overflow, then we can determine  $R_{r2}$ :

$$R_{r2} \leq R_{r2,\max} = \frac{-R_{x,\max} \cdot t_{2,\max}}{t_{2,\max} - R_{x,\max} \cdot C_{x,\max} \cdot \ln \alpha} \quad (11)$$

Thus, we have  $R_{r2,\max} = 164$  M $\Omega$  for  $N = 16$ , and  $R_{r2,\max} = 8.9$  M $\Omega$  for  $N = 15$ . We should not forget about the additional parasitic capacitances and the measurement errors that can result in exceeding the measuring range of the timer. For this reason, the following resistance value from the



E6 series was selected:  $R_{r2} = 10 \text{ M}\Omega$ . For this value:  $2^{15} \cdot t_{clk} < t_{2,max} = 34764 \cdot t_{clk} = 2.2 \text{ ms} < 2^{16} \cdot t_{clk}$ , and  $t_{2,min} = 2340 \cdot t_{clk} = 0.1462 \text{ ms} > 2^{11} \cdot t_{clk}$ .

Determination of the  $R_{r1}$  value is more complex. It follows from (5) and (8) that to minimise the discretisation error of the time measurements, two opposite criteria must be met: if the value of  $R_{r1}$  increases,  $t_1$  also increases, but  $(t_2 - t_1)$  decreases. Hence a compromise must be chosen:  $t_1 > 2^n \cdot t_{clk}$ , and  $(t_2 - t_1) > 2^n \cdot t_{clk}$ . The smallest values of  $t_1$  and  $(t_2 - t_1)$  are determined for  $C_{x,min}$  and  $R_{x,min}$ . For these values, functions  $t_1(R_{r1})$  and  $(t_2 - t_1)(R_{r1})$  are drawn in Fig. 6. It can be seen in Fig. 6 that this condition is fulfilled for  $n = 10$ , that is, for  $R_{r1}$  from  $0.066 \cdot R_{r2}$  to  $0.105 \cdot R_{r2}$ . Therefore the value  $R_{r1} = 0.1 \cdot R_{r2} = 1 \text{ M}\Omega$  from the series E6 was chosen. For this value:  $t_{1,min} = 1288 \cdot t_{clk} = 80.5 \text{ }\mu\text{s} > 2^{10} \cdot t_{clk}$ , and  $t_{1,max} = 6316 \cdot t_{clk} = 394.75 \text{ }\mu\text{s} > 2^{12} \cdot t_{clk}$ .

### 3. Error analysis

The accuracy of determining the values of  $C_x$  and  $R_x$  is burdened with random and systematic errors. The random errors are related to the measurement errors of the discharging times  $t_1$  and  $t_2$ , which will be discussed in the next subsections.

The systematic errors are caused by the uncertainty of the constant circuit parameters  $R_{r1}$ ,  $R_{r2}$ , and  $\alpha$  (4) (8), but above all by the influence of the non-ideality of the port pins of the microcontroller and the parasitic capacitances  $C_{p1}$ ,  $C_{p2}$ , and  $C_{p3}$  representing, inter alia, capacitances between the printed circuit board traces. It follows from the fact that the values of capacitance  $C_x$  are in a range of between 100 pF and 286 pF, and the pin capacitance  $C_{pin}$  is at a similar level (about 10 pF). The model of the interface circuit, taking into account the pin parameters of the microcontroller, is shown in Fig. 7.

Whereas output pin resistance  $R_{pin\_on}$ , at a low voltage level, is around 25  $\Omega$ , input pin resistance  $R_{pin\_off}$  is estimated at around 3 G $\Omega$  or more [35, page 67]. That is, they can be omitted in the simplified model of the interface circuit (Fig. 8), because  $R_{pin\_on} \ll R_{rk}$ , and  $R_{rk} \parallel R_x \ll R_{pin\_off}$ , and  $R_{pin\_off}$  is connected in parallel with  $C_{pin}$ . In this case, the measured value of the sensor capacitance is  $C_m \approx C_x + C_{pin3} + C_{p3}$ , and the measured value of the sensor shunt resistance should be  $R_m \approx R_x$ . We can assume that  $C_{pink} = C_{pin} + C_{pk}$ . Two approaches of systematic error correction to minimise these errors are proposed in Subsections 4.1 and 4.2.

#### 3.1. Assessment of uncertainty for determination of $R_x$

As presented in [24,27,36], the maximum possible relative uncertainty (error) of an indirectly measurable variable  $y = f(x_1, \dots, x_L)$  is the sum of the maximum relative uncertainties  $df(x_i)$  of the directly measurable variables  $x_l$  ( $l = 1, 2, \dots, L$ ). The relative uncertainties  $df(x_i)$  are given by the formula:

$$df(x_i) = \frac{1}{|f(x_1, x_2, \dots, x_L)|} \cdot \left| \frac{\partial f}{\partial x_i} \right| \cdot |\Delta x_i|, \quad (12)$$

where:  $\Delta x_i$  is the maximum absolute uncertainty of a directly measurable variable  $x_i$ .

It follows from (4) that indirectly measurable resistance  $R_x$  depends on directly fixed/measurable variables  $R_{r1}$ ,  $R_{r2}$ ,  $t_1$ , and  $t_2$ . For these directly variables based on (12), the relative uncertainties  $dR_x(R_{r1})$ ,  $dR_x(R_{r2})$ ,  $dR_x(t_1)$ , and  $dR_x(t_2)$  were derived:

$$dR_x(R_{r1}) = \frac{R_{r2} \cdot t_1}{R_{r2} \cdot t_1 - R_{r1} \cdot t_2} \cdot \frac{\Delta R_{r1}}{R_{r1}} \quad (13)$$

$$dR_x(R_{r2}) = \frac{R_{r1} \cdot t_2}{R_{r2} \cdot t_1 - R_{r1} \cdot t_2} \cdot \frac{\Delta R_{r2}}{R_{r2}} \quad (14)$$

$$dR_x(t_1) = \frac{t_2 \cdot (R_{r1} - R_{r2})}{(t_2 - t_1) \cdot (R_{r2} \cdot t_1 - R_{r1} \cdot t_2)} \cdot \Delta t_1 \quad (15)$$

$$dR_x(t_2) = \frac{t_1 \cdot (R_{r2} - R_{r1})}{(t_2 - t_1) \cdot (R_{r2} \cdot t_1 - R_{r1} \cdot t_2)} \cdot \Delta t_2 \quad (16)$$

Components  $\Delta R_{rk} / R_{rk}$  of formulae (13) and (14) contain the tolerance of  $R_{rk}$  and the influence of the thermal drift affecting  $R_{rk}$  [27]. They are small (e.g. 0.01% or 0.0023% if we use Agilent 34410A [37] to measure the  $R_{rk}$  values or if we use precision resistors with a tolerance equal to or better than 0.05%) in comparison with the  $\Delta t_k$  components of formulae (15) and (16), hence they can be neglected.

The  $\Delta t_k$  components represent the effects of both quantisation and above all trigger noise, that is, the inaccuracy of the functioning of the AC, where  $\Delta t_k = f_k(\Delta v_{1,k}, R_{rk}, R_x, C_x)$ , and  $\Delta v_{1,k}$  is the noise (disturbances) generated, inter alia, by the digital circuits of the microcontroller [27].

Based on the fact that  $v_1/V_{in} = c_{DAC}/2^N$ , and  $\Delta v_{1,k}/V_{in} = \Delta c_{DAC,k}/2^N$ , formulae included in Table 1, and the assumption that  $t_k' = t_k + \Delta t_k$ , we can derive the following formula for  $\Delta t_k$ :

$$\Delta t_k = -R_x \parallel R_{wk} \cdot C_x \cdot \ln \left( 1 + \frac{\Delta c_{DAC,k}}{c_{DAC}} \right), \quad k = 1, 2. \quad (17)$$

It was also observed during experimental studies that as the value of  $R_{rk} \parallel R_x$  increases, the noise level also increases. For this reason, it was established that  $\Delta t_1$  is plotted for  $\Delta c_{DAC,1} = 4$ , and  $\Delta t_2$  for  $\Delta c_{DAC,2} = 12$  in Fig. 9. Graphs of  $dR_x(t_1)$  and  $dR_x(t_2)$  were drawn also for these  $\Delta t_k$  values in Fig. 10. It can be seen that  $dR_x(t_1)$  is in the range of 0.29% to 0.37%, and  $dR_x(t_2)$  is in the range of 0.87% to 1.1%.

### 3.2. Assessment of uncertainty for determination of $C_x$

As before, based on (7), the relative inaccuracies  $dC_x(\alpha)$ ,  $dC_x(R_{r1})$ ,  $dC_x(R_{r2})$ ,  $dC_x(t_1)$ , and  $dC_x(t_2)$  for the indirectly measurable capacitance  $C_x$ , which depends on directly variables  $\alpha$ ,  $R_{r1}$ ,  $R_{r2}$ ,  $t_1$ , and  $t_2$ , were derived:

$$dC_x(\alpha) = \frac{\Delta\alpha}{\alpha \cdot \ln \alpha} \quad (18)$$

$$dC_x(R_{r1}) = \frac{R_{r2}}{R_{r2} - R_{r1}} \frac{\Delta R_{r1}}{R_{r1}} \quad (19)$$

$$dC_x(R_{r2}) = \frac{R_{r1}}{R_{r2} - R_{r1}} \frac{\Delta R_{r2}}{R_{r2}} \quad (20)$$

$$dC_x(t_1) = \frac{t_2}{t_2 - t_1} \cdot \frac{\Delta t_1}{t_1} \quad (21)$$

$$dC_x(t_2) = \frac{t_1}{t_2 - t_1} \cdot \frac{\Delta t_2}{t_2} \quad (22)$$

As was previously shown,  $dC_x(R_{r1})$ ,  $dC_x(R_{r2})$ , and  $dC_x(\alpha)$  [27] can also be neglected. The graphs of  $dR_x(t_1)$  and  $dR_x(t_2)$  were drawn in Fig. 11. In this case,  $dC_x(t_1)$  is in the range of 0.18% to 0.37%, and  $dC_x(t_2)$  is in the range of 0.1% to 0.55%.

## 4. Materials and methods

The proposed measurement method for lossy capacitive sensors was experimentally examined based on the compact smart sensor shown in Fig. 3. The ATXmega32A4 microcontroller's timer/counter TC0 is clocked directly by the system clock ( $t_{clk} = 62.5$  ns). The value written to the DAC data register DACB\_CH0DATA  $c_{DAC} = 814$ , which makes  $v_{DAC} = 0.66064$  V ( $\alpha = 0.2002$ ). The supply voltage  $V_{CC} = 3.3008$  V, and the measured values of the reference resistors are as follows:  $R_{r1} = 1.00053$  M $\Omega$ , and  $R_{r2} = 10.0092$  M $\Omega$ . All voltages and resistances were measured with an Agilent 34410A Digital Multimeter. A photograph of the prototype of the smart sensor shown in Fig. 12.

The lossy capacitive sensor was emulated by a set of discrete components (i.e. a capacitor in parallel with a resistor). It used twelve ceramic capacitors  $\{C_{x,i}\}_{i=1,\dots,12}$  whose values were measured by an Agilent 4263B LCR METER at 1 kHz using a 16047A Test Fixture by Hewlett-Packard (Table 2). Seven metal film resistors  $\{R_{x,j}\}_{j=1,\dots,7}$  were also used (the THT assembly, with

a power rating of 0.6 W,  $\phi 2.5 \times 6.8$  mm, TCR =  $50 \cdot 10^{-6}/^{\circ}\text{C}$ ) with the reference values included in Table 3.

Table 2. A set of capacitors used to emulate the capacitance  $C_x$  of the sensor.

| $i$            | 1      | 2      | 3      | 4      | 5      | 6      | 7      | 8      | 9      | 10     | 11     | 12     |
|----------------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|
| $C_{x,i}$ [pF] | 100.06 | 108.94 | 119.82 | 131.14 | 146.83 | 162.97 | 179.53 | 182.21 | 199.94 | 219.65 | 239.37 | 285.85 |

Table 3. A set of resistors used to emulate the shunt resistance  $R_x$  of the sensor.

| $j$                     | 1       | 2       | 3      | 4      | 5      | 6      | 7       |
|-------------------------|---------|---------|--------|--------|--------|--------|---------|
| $R_{x,j}$ [M $\Omega$ ] | 1.00212 | 2.18195 | 3.2994 | 4.7034 | 6.8426 | 8.2014 | 10.0015 |

The measurements were carried out 1024 times for all combinations of  $C_{x,i}$  and  $R_{x,j}$  values, and for a single measurement of times and for multiple measurements of times ( $M = 64$ ) [27]. Therefore, for each pair of  $C_{x,i}$  and  $R_{x,j}$ ,  $1024 \cdot (1 + 64) = 66,560$  measurements were performed, which gives a total of  $12 \cdot 7 \cdot 66,560 = 5,591,040$  measurements. E.g. for the assumed capacitance and resistance ranges of a sensor,  $t_{clk} = 62.5$  ns and  $M = 64$ , the duration for multiple measurements procedure is in a range between about 15 ms and 167 ms.

After each  $h$ -th single and  $M$ -multiple measurement ( $h = 1, \dots, 1024$ ) for each  $i, j$ -th combination, the measured values of discharging times in raw form, i.e. in the form of a value directly read from the timer/counter TC0, of the first time  $\tau_{1,i,j,h}$  and the second time  $\tau_{2,i,j,h}$  and also the  $C_{m,i,j,h}$  and  $R_{m,i,j,h}$  values calculated by the microcontroller based on (23) and (24), were sent to a personal computer via a USB interface.

$$R_{m,i,j,h} = R_{r2} \frac{(\tau_{2,i,j,h} - \tau_{1,i,j,h})}{\xi \cdot \tau_{1,i,j,h} - \tau_{2,i,j,h}} \quad (23)$$

$$C_{m,i,j,h} = \gamma \cdot t_{clk} \cdot \frac{\tau_{1,i,j,h} \cdot \tau_{2,i,j,h}}{\tau_{2,i,j,h} - \tau_{1,i,j,h}} \quad (24)$$

where,  $\tau_{k,i,j,h} = t_{k,i,j,h}/t_{clk}$ ,  $i = 1, 2, \dots, 12$ ,  $j = 1, 2, \dots, 7$ , and  $h = 1, 2, \dots, 1024$ .

Each time, for each  $X_{i,j}$  value, where  $X_{i,j}$  represented  $\tau_{1,i,j}$ ,  $\tau_{2,i,j}$ ,  $C_{m,i,j}$ , and  $R_{m,i,j}$ , the lowest  $X_{i,j,min} = \min_h \{X_{i,j,h}\}$ , highest  $X_{i,j,max} = \max_h \{X_{i,j,h}\}$ , and mean  $X_{i,j,mean} = (X_{i,j,min} + X_{i,j,max})/2$ , values from the sets  $\{X_{i,j,h}\}_{h=1, \dots, 1024}$  of measurement and calculation results were determined and calculated. The absolute  $\Delta X_{i,j}$  and relative  $dX_{i,j}$  measurement errors were also defined:

$$\Delta X_{i,j} = X_{i,j,mean} - X_{i,j,reference} \quad (25)$$

$$dX_{i,j} = \frac{\Delta X_{i,j}}{X_{i,j,reference}} \cdot 100\% \quad (25)$$

where  $X_{i,j,reference}$  is the reference value or the value calculated from the theoretical data.

## 5. Experimental results and discussion

The measurement results of scaling of the interface circuit for the  $\tau_{k,mean}$  values are given in Fig. 13. Whereas the absolute measurement errors  $\Delta t_1$  and  $\Delta t_2$  of these times for single measurements are plotted in Fig. 14. Comparing the surfaces in this figure with the surfaces in Fig. 9, we can conclude that as the  $R_{rk} \parallel R_x$  value increases, the noise level also increases. E.g. for the  $\Delta t_1$  plot, that is, if we use  $R_{r1}$ , it is on the level of about 3 mV ( $\Delta C_{DAC}$  about 4), and for the  $\Delta t_2$  plot, that is, if we use  $R_{r2}$ , it is on the level of about 10 mV ( $\Delta C_{DAC}$  about 12), which is an adverse phenomenon.

Fig. 15 shows the experimental relative errors  $dC_m$  and  $dR_m$  in the measurements of the  $C_x$  and  $R_x$  values. The values of  $dC_m$  are in the range from 3.2% to 14.7%, and the values of  $dR_m$  are in the range from 4.3% to 19.2%. They are at a similar level as for the method proposed in [22].

For large  $R_x$  values, the  $dC_m$  error is at a constant level. However, the smaller the  $C_x$  values, the larger this error. This follows from the fact that the measured value  $C_m$  includes, apart from  $C_x$ , also the input capacitances of the port pins and parasitic capacitances (Fig. 8). These additional capacitances introduce an absolute error value between 8 pF and 19.2 pF.

Also, the values of error  $dR_m$  depend on the values of  $C_x$  and  $R_x$  simultaneously. The measured value  $R_m$  of  $R_x$  is 66 k $\Omega$  to 1.97 M $\Omega$  larger than the set  $R_x$  values. This is due to the extension of the discharging times  $t_1$  and especially  $t_2$ , which is caused by the need to discharge additional parasitic capacitances by  $R_{rk} \parallel R_x$ . Therefore, the smaller the  $C_x$  values, the greater the impact of the other capacitances on the measurement results.

Hence, errors  $dC_m$  and  $dR_m$  are caused mainly by parasitic capacitances existing in the interface circuit. They belong to systematic errors, and therefore they can be software corrected based on the results of scaling of the interface circuit, which will be shown in the following subsections.

The effect of noise on the measurement accuracy was also tested. In this case, the relative random errors  $dX_{i,j,noise}$  are defined in the following way:

$$dX_{i,j,noise} = \frac{\Delta X_{i,j,max} - \Delta X_{i,j,min}}{2 \cdot X_{i,j,reference}} \cdot 100\% \quad (26)$$

The relative random errors  $dC_{noise}$  and  $dR_{noise}$  for single measurements are plotted in Fig. 16, and for multiple measurements, in Fig. 17. In the first case,  $dC_{noise}$  is in the range from  $\pm 0.29\%$  to

$\pm 0.71\%$ , and  $dR_{noise}$  is in the range from  $\pm 0.64\%$  to  $\pm 2.3\%$ . Fig. 16 shows that error  $dC_{noise}$  decreases as the  $C_x \cdot R_x$  time constant increases. Whereas the values of  $dR_{noise}$  are mainly determined by the values of  $C_x$ .

For the approach in which  $t_1$  and  $t_2$  are measured  $M = 64$  times and then averaged [27], these errors have the following values:  $dC_{noise}$  is in the range from  $\pm 0.04\%$  to  $\pm 0.19\%$ , and  $dR_{noise}$  is in the range from  $\pm 0.09\%$  to  $\pm 0.55\%$  (Fig. 17). Thanks to this approach, errors were reduced by about 3.7–7.25 times for  $dC_{noise}$  and about 4.2–7.1 times for  $dR_{noise}$ .

This allowed a resolution of measuring capacitance from 0.05 pF to 0.34 pF to be obtained, which is a satisfactory result (as presented in [5] for commercial capacitive RH sensors [32,33], the sensitivity varies from 0.2 pF up to 0.5 pF per 1% of RH), and a resolution for measuring resistance from 1.2 k $\Omega$  to 55.7 k $\Omega$  to be obtained.

### 5.1. Graphic approach to systematic error correction

The first proposal to reduce systematic errors is a graphic approach. Fig. 18a shows the scaling curves for  $C_x$  plotted for the  $R_x$  parameter placed in three-dimensional space with coordinates  $t_1$ ,  $t_2$ , and  $C_x$  (left graph), and scaling curves for  $R_x$  this time plotted for the  $C_x$  parameter placed in space with coordinates  $t_1$ ,  $t_2$ , and  $R_x$  (right graph), where  $t_1$ ,  $t_2$  are the measured discharging time values, and  $C_x$ , and  $R_x$  are the reference values. These spaces together with the curves can be projected onto planes with the coordinates  $t_1$ ,  $t_2$  as shown in Fig. 18b. In the last step, we can superimpose one plane with the  $C_x$  curves onto the other plane with the  $R_x$  curves. In this way, we obtain the scaled mesh shown in Fig. 19. This mesh can be scaled: the  $C_x$  curves in picofarads, and the  $R_x$  curves in megohms.

Using this approach, the determination of the corrected  $C_{corr}$  and  $R_{corr}$  values of  $C_x$  and  $R_x$  consists in placing the measurement point E with coordinates  $t_1$  and  $t_2$  on a plane with a scaled mesh (Fig. 19). Then, this point is projected onto the scaled  $R_x$  curve along the  $C_x$  curve and onto the scaled  $C_x$  curve along the  $R_x$  curve. We read the  $C_{corr}$  and  $R_{corr}$  values from these curves.

The advantage of this approach is that we read the corrected values of  $C_x$  and  $R_x$  directly from the scaled mesh based on only the measured values  $t_1$  and  $t_2$ .

Unfortunately, this solution has significant disadvantages that impede its implementation in the microcontroller software. Scales on  $C_x$  and  $R_x$  curves are nonlinear, and the trajectories of the projections are not straight lines.

### 5.2. Numerical approach to systematic error correction

The second proposal to reduce systematic errors, based on a correction dictionary, was implemented in the microcontroller software. The correction dictionary is a set of data used for

correction. It was named by analogy with fault dictionaries, which are data sets used for fault detection and location in analogue electronic circuits [38,39].

This set is determined as follows. In the first step, a set of curves  $C_{x,j} = f_j(C_{m,i,j}, R_{m,i,j})$  was plotted in a space with coordinates  $C_m, R_m, C_x$ , and a set of curves  $R_{x,i} = f_i(C_{m,i,j}, R_{m,i,j})$  was plotted in a space with coordinates  $C_m, R_m, R_x$  (Fig 20). It is desirable that  $C_{corr} = C_x$ , and  $R_{corr} = R_x$ . Therefore, the  $C_{corr}$  curves are an approximation of the  $C_x$  curves using a straight line (27), and the  $R_{corr}$  curves are an approximation of the  $R_x$  curves using a quadratic function (28):

$$C_{corr} = A_1 \cdot C_m + A_2 \quad (27)$$

$$R_{corr} = B_1 \cdot R_m \cdot R_m + B_2 \cdot R_m + B_3 \quad (28)$$

where:  $A_1$ , and  $A_2$  are the coefficients of the linear function depended on  $R_m$ , and  $B_1, B_2$ , and  $B_3$  are the coefficients of the quadratic function depended on  $C_m$  (as shown in the projections on the plane  $C_m, R_m$  in Fig. 20).

Graphs of  $A_1, A_2$  as a function of  $R_m$  are drawn in Fig. 21a, and graphs of  $B_1, B_2, B_3$  as a function of  $C_m$  in Fig. 21b. It was tested based on the Matlab function polyfit and found that the curves of these coefficients are best approximated by third-degree polynomials  $P(\cdot)$  (dashed lines in the graphs in Fig. 21). Hence, they can be described by:

$$A_1 = P(R_m, \{d_{1,p}\}_{p=1,\dots,4}) \quad (29a)$$

$$A_2 = P(R_m, \{d_{2,p}\}_{p=1,\dots,4}) \quad (29b)$$

$$B_1 = P(C_m, \{e_{1,p}\}_{p=1,\dots,4}) \quad (29c)$$

$$B_2 = P(C_m, \{e_{2,p}\}_{p=1,\dots,4}) \quad (29d)$$

$$B_3 = P(C_m, \{e_{3,p}\}_{p=1,\dots,4}) \quad (29e)$$

where  $\{d_{1,p}, d_{2,p}, e_{1,p}, e_{2,p}, e_{3,p}\}_{p=1,\dots,4}$  are the coefficients of individual third-degree polynomials, and they create the correction dictionary. Therefore this dictionary is small because it consists of only 20 elements of the type 'double'. That is, it occupies only 160 bytes of a program memory of the microcontroller.

Hence the systematic error correction algorithm based on this approach is as follows:

1. Values of  $R_m$ , and  $C_m$  are calculated based on the measured values of times  $t_1$  and  $t_2$ , and (23) and (24).
2. Values of  $A_1$ , and  $A_2$  are calculated based on  $R_m$  and  $\{d_{1,p}, d_{2,p}\}_{p=1,\dots,4}$ , and (29a) and (29b).

3. Values of  $B_1$ ,  $B_2$ , and  $B_3$  are calculated based on  $C_m$  and  $\{e_{1,p}, e_{2,p}, e_{3,p}\}_{p=1,\dots,4}$ , and (29c), (29d) and (29e).
4. Value of  $C_{corr}$  is calculated based on the values of  $C_m$ ,  $A_1$ , and  $A_2$ , and (27).
5. Value of  $R_{corr}$  is calculated based on the values of  $R_m$ ,  $B_1$ ,  $B_2$ , and  $B_3$ , and (28).

This algorithm was implemented as the function written in ANSI C. It occupies only 1428 Bytes of the program memory and uses 80 Bytes of the SRAM of the microcontroller. Execution time for this function is short. It is about 0.46 ms for an 8-bit microcontroller runs on a crystal oscillator with  $f_{clk} = 16$  MHz.

Thanks to the presented solution, it is possible to reduce the systematic error up to about 23 times for  $C_x$ , and up to about 66 times for  $R_x$ , as shown in Fig. 22. In this case, the values of  $dC_m$  are in the range from -0.55% to 0.64%, and the values of  $dR_m$  are in the range from -0.46% to 0.3%. It provides a measuring capacitance resolution from 0.99 pF to 1.83 pF, which, despite everything, is a satisfactory result, especially for using such a simple correction method based on such a small correction dictionary. The improvement of the resistance measurement resolution is also significant. It is in the range from 4.6 k $\Omega$  to 30.3 k $\Omega$ .

In summary, when we take into account both systematic and random errors, we obtain a measurement relative uncertainty (relative error) of capacitance of less than 0.71% (resolution < 2.03 pF for the range 100–286 pF), and a resistance uncertainty of less than 0.74% (resolution < 58.61 k $\Omega$  for the range 1–10 M $\Omega$ ). However, if we narrow the range of measured capacitances to the range of capacitances corresponding to e.g. the HS1101LF sensor (we take into account  $C_{x,6} - C_{x,9}$ ), then the relative uncertainty of capacitance is less than 0.57% and resolution < 0.08 pF, which in turn corresponds to at least 0.26% RH resolution of this sensor [32].

## 6. Comparison of the method with the state of the art

The proposed measurement method is compared with a modified 3-point calibration technique (3-PCT) [22], because both methods are based on direct sensor-to-microcontroller interface circuits dedicated to lossy capacitive sensors. The first method was developed for grounded sensors, whereas the second one is for floating sensors. The results of the comparison are included in Table 4. The table also includes a comparison of methods dedicated to perfect capacitive sensors proposed in [27] and [5], because the concepts of the proposed method and the 3-PCT are derived from these methods, respectively.



Table 4. Comparison of the proposed method with the modified 3-point calibration technique.

| Reference  | $C_x$ and $R_x$ range                | Circuit topology | Built-in peripherals                                  | $C_x$ and $R_x$ accuracy (% error)                                   | Measurement time               |
|------------|--------------------------------------|------------------|---|--|--------------------------------|
| This work  | 100–286 pF<br>and<br>1–10 M $\Omega$ | $R_{r1}, R_{r2}$ | 3 I/O pins, timer, AC, and a voltage reference source | < 1.1 (< 0.71 <sup>*</sup> )<br>and<br>< 2.75 (< 0.74 <sup>*</sup> ) | $t_1 + t_2$                    |
| 3-PCT [20] | 150–206 pF<br>and<br>1–10 M $\Omega$ | $R_d, R_i, C_c$  | 3 I/O pins, timer                                     | < 6<br>and<br>not specified  | $T_x + T_c + T_{off} + T_{ad}$ |
| [27]       | 100–225 pF<br>and<br>>>10 M $\Omega$ | $R_r$            | 2 I/O pins, timer, AC, voltage reference source       | <0.081 (<0.057 <sup>*</sup> )<br>and<br>not taken into account       | $t_m$                          |
| [5]        | 149–206 pF<br>and<br>>>10 M $\Omega$ | $R_d, R_i, C_c$  | 3 I/O pins, timer                                     | <0.036 for $M = 100$<br>and<br>not taken into account                | $T_x + T_c + T_{off}$          |

\* – for an  $M$ -multiple measurement approach ( $M = 64$ )

where:

$T_x, T_c, T_{off}, T_{add}$  — sensor, reference, offset, and additional measurement discharging times,

$t_m$  — time of charging  $C_x$  via  $R_r$  to  $V_m$ .

We can see in Table 4 that an important advantage of the proposed measurement method is the about six times smaller relative error of capacitance measurement for a single measurement approach (ten times smaller for an  $M$ -multiple measurement approach) with respect to the modified 3-PCT method. The authors in [22] presented data for  $C_x = 150$  pF. Whereas, for the proposed method and for a similar value,  $C_{x,5} = 146.83$  pF, a relative error less than 0.75% (0.37%) was obtained, that is, about an 8-fold (16-fold) improvement in the measurement accuracy.

Another advantage is that we used resistors instead of a capacitor as a reference element. This follows from the fact that resistors are characterised by high precision of performance and low temperature coefficient of resistance relative to capacitors.

If we assume that the discharging times for the modified 3-PCT method and the proposed method are similar for maintaining the same measurement resolution of the timer of the microcontroller, we can conclude that the total measurement time of the proposed method is about two times shorter, what is the final advantage of the proposed method as it lowers energy consumption as shown in [27]. It follows from the fact that the core processor consumes the most

energy. E.g. for the ATXmega32A4 microcontroller the power supply current in the active mode at 3.3 V, for a 16 MHz external clock and at 25°C is equal to about 7.5 mA [35, page 70]. Whereas the AC current consumption (low-speed) is 110  $\mu$ A, and the DAC consumes less than 1.1 mA in the low-power mode. The timer current consumption (Prescaler DIV1) is 19  $\mu$ A [35, page 62]. That is, the total current consumption for the proposed method is only 8.73 mA. For the modified 3-PCT method this consumption is 7.52 mA. Hence, the energy consumption has decreased about by 1.72 times due to a two-fold reduction in the measurement time.

## 7. Conclusions

In the paper, a new time-domain measurement method is presented for determining the capacitance and resistance values of lossy relative humidity capacitive sensors, dedicated, among others, to grounded sensors, based on a direct sensor-to-microcontroller interface circuit. The method is designed for microcontrollers equipped with internal analog comparators and timers. The interface circuit consists only of four reference resistors (two reference resistors if a microcontroller includes a voltage reference source) and a sensor. In this method, we proposed: a new structure of the interface circuit, a new measurement procedure and its implementation in a microcontroller software, a new graphic approach to systematic error correction and a new systematic error correction algorithm based on a correction dictionary.

The experimental investigations were performed based on an example of a complete application in the form of a prototype based on an 8-bit ATXmega32A4 microcontroller. The experiments confirmed that relative errors of measurement of capacitance introduced by the interface circuit are less than 0.71%, which corresponds to a capacitance measurement resolution less than 2.05 pF for a range of the measured capacitance values from 100 pF to 286 pF, and relative errors of measurement of resistance are less than 0.74% (a resistance measurement resolution of less than 58.61 k $\Omega$  for a range of the measured resistance values from 1 M $\Omega$  to 10 M $\Omega$ ).

Such good results were obtained thanks to the implementation of a systematic error correction algorithm based on a correction dictionary and the  $M$ -multiple measurement approach in the microcontroller software.

The software written for this method was implemented in an 8-bit microcontroller, which confirms that the low computing power and limited program and data memories of 8-bit microcontrollers are enough for this method. Thanks to this, based on the proposed solution, we can extend the functionality of existing microcontroller systems with direct sensor-to-microcontroller interface circuits in a cheap and simple way.

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## Figures captions

Fig. 1. Scheme of a proposed direct sensor-to-microcontroller interface circuit.

Fig. 2. Timing of the signal  $v_{out}(t)$  at the Pin 3 of the sensor interface circuit for  $V_{in} = 3.3$  V,  $R_{r1} = 1$  M $\Omega$ ,  $R_{r2} = 10$  M $\Omega$ ,  $R_x = 10$  M $\Omega$ ,  $C_x = 100$  pF.

Fig. 3. Block scheme of the compact smart lossy capacitive sensor based on the ATxmega32A4 microcontroller.

Fig. 4. The flowchart of the algorithm of the measurement procedure.

Fig. 5. Graph of the maximum relative uncertainty  $dC_x(\alpha)$  as a function of the voltage ratio  $\alpha = v_1/V_{in}$ .

Fig. 6. Graph of functions  $t_1(R_{r1}/R_{r2})$  and  $(t_2 - t_1(R_{r1}/R_{r2}))$  for  $R_{r2} = 10$  M $\Omega$ .

Fig. 7. Circuit model of a direct capacitive sensor-to-microcontroller interface circuit.

Fig. 8. Simplified circuit model of the interface circuit from Fig. 6 for the step II of the measurement procedure.

Fig. 9. Maximum absolute uncertainties  $\Delta t_1$  and  $\Delta t_2$  of discharging times  $t_1$  and  $t_2$  determination, where  $\Delta t_1$  is plotted for  $\Delta C_{DAC,1} = 4$ , and  $\Delta t_2$  for  $\Delta C_{DAC,2} = 12$ .

Fig. 10. Relative uncertainties  $dR_x(t_1)$  and  $dR_x(t_2)$  of  $R_x$  determination.

Fig. 11. Relative uncertainties  $dC_x(t_1)$  and  $dC_x(t_2)$  of  $C_x$  determination.

Fig. 12. Prototype of the proposed circuit for interfacing the lossy capacitive sensor.

Fig. 13. Graphs of the measurement results  $t_1$  and  $t_2$  of scaling of the interface circuit.

Fig. 14. Absolute measurement errors  $\Delta t_1$  and  $\Delta t_2$  of times  $t_1$  and  $t_2$  for a single measurement approach.

Fig. 15. Relative systematic measurement errors  $dC_m$  and  $dR_m$  in the measurements of  $C_x$  and  $R_x$  values.

Fig. 16. Relative random measurement errors  $dC_{noise}$  and  $dR_{noise}$  in the measurements of  $C_x$  and  $R_x$  values for a single measurement approach.

Fig. 17. Relative random measurement errors  $dC_{noise}$  and  $dR_{noise}$  in the measurements of  $C_x$  and  $R_x$  values for a multiple measurement approach ( $M = 64$ ).

Fig. 18. Scaling curves for  $C_x$  plotted for the  $R_x$  parameter (left graphs) and scaling curves for  $R_x$  plotted for the  $C_x$  parameter (right graphs): a) in three-dimensional space, b) on the plane with coordinates  $t_1, t_2$ .

Fig. 19. Scaled mesh on the plane with coordinates  $t_1, t_2$ , where the  $C_x$  curves are in picofarads, and the  $R_x$  curves in megohms

Fig. 20. Sets of curves: a)  $C_{x,j} = f_j(C_{m,i,j}, R_{m,i,j})$  in a space with coordinates  $C_m, R_m, C_x$ , b)  $R_{x,i} = f_i(C_{m,i,j}, R_{m,i,j})$  in a space with coordinates  $C_m, R_m, R_x$ .

Fig. 21. Graphs of coefficients: a)  $A_1, A_2$  in a function of  $R_m$ , b)  $B_1, B_2, B_3$  in a function of  $C_m$ .

Fig. 22. Relative systematic measurement errors  $dC_m$  and  $dR_m$  in the function of  $C_m$  and  $R_m$  values after software correction.

## Table captions

Table 1. State of pins 1, 2 and 3 and resulting discharging times  $t_1$  and  $t_2$ .

Table 2. A set of capacitors used to emulate the capacitance  $C_x$  of the sensor.

Table 3. A set of resistors used to emulate the shunt resistance  $R_x$  of the sensor.

Table 4. Comparison of the proposed method with the modified 3-point calibration technique.



Figure 1

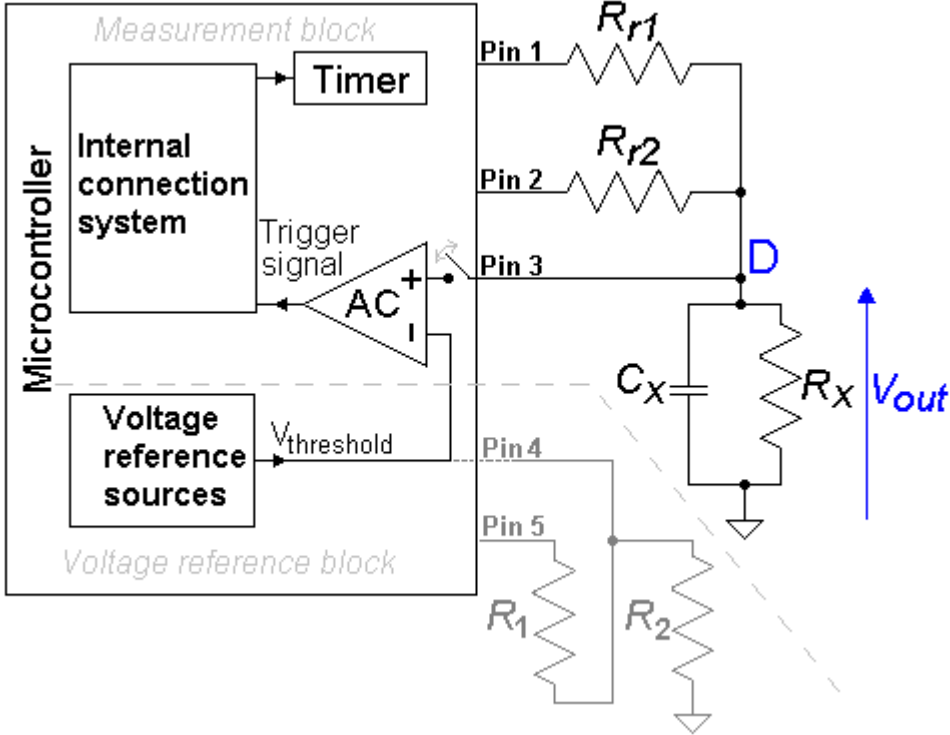


Figure 2

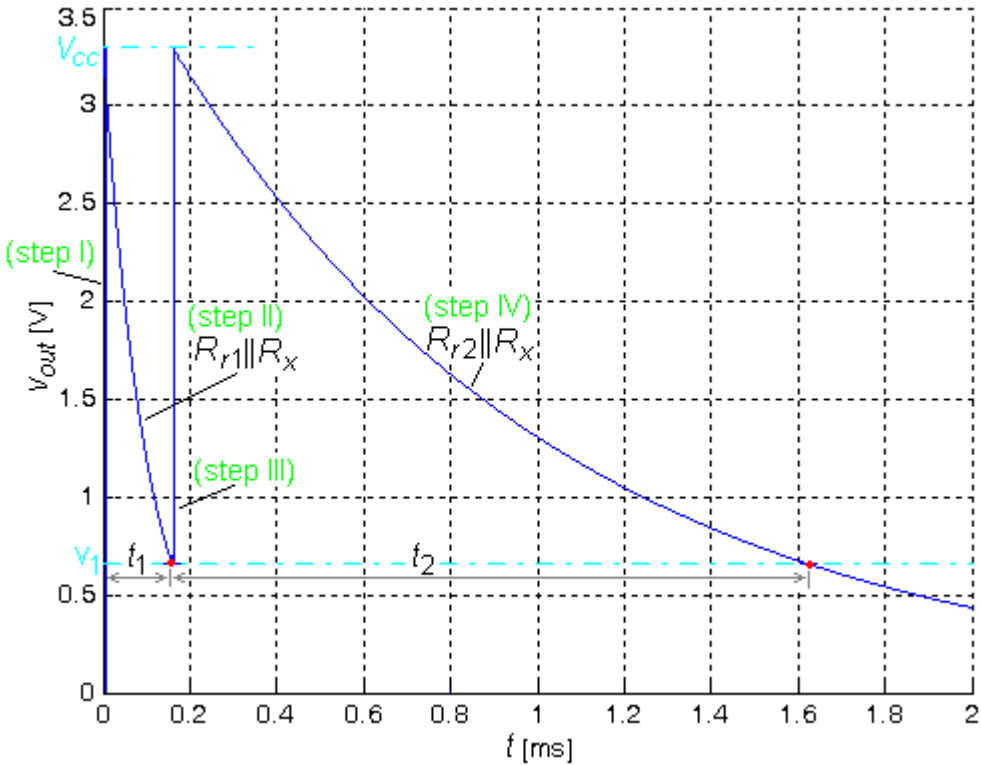


Figure 3

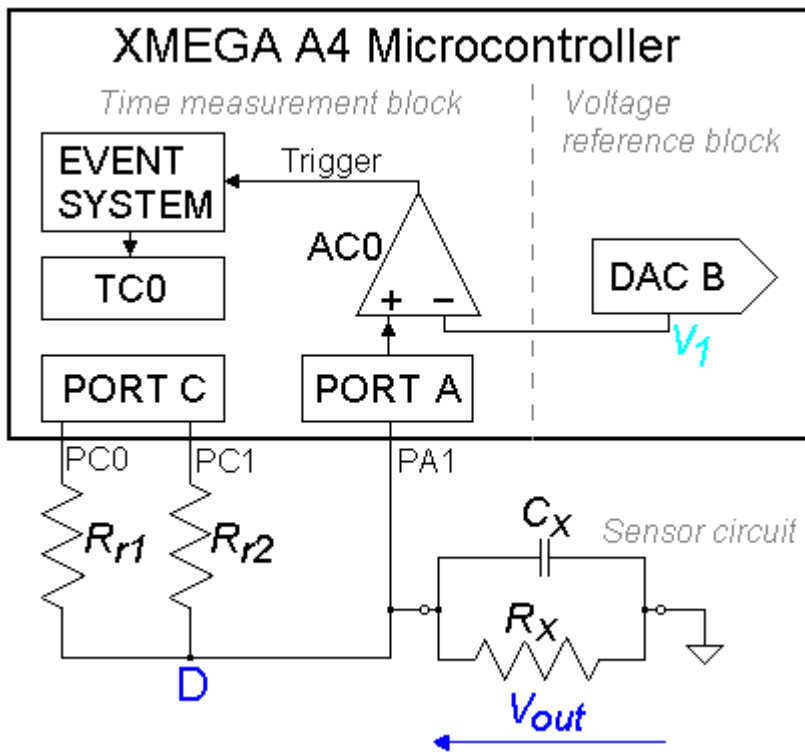


Figure 4

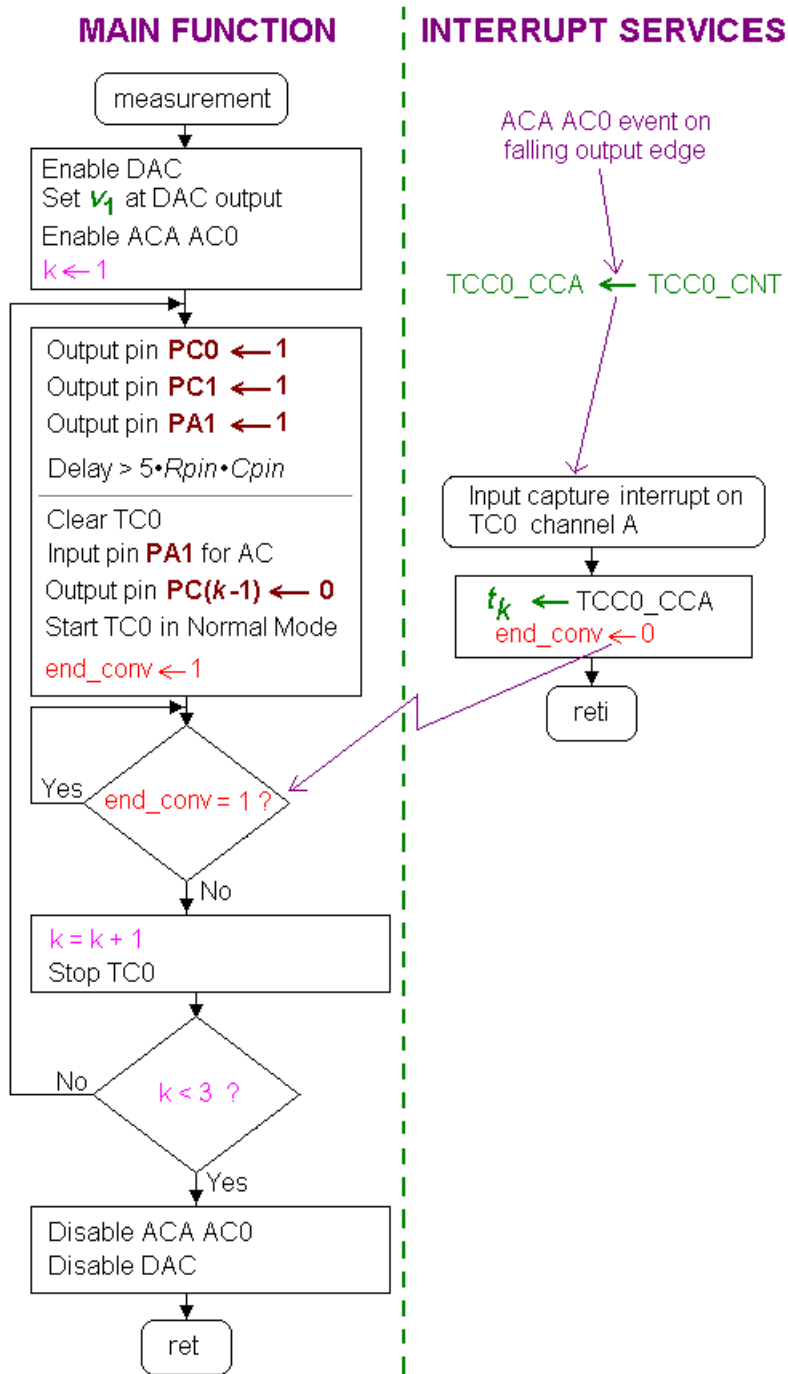


Figure 5

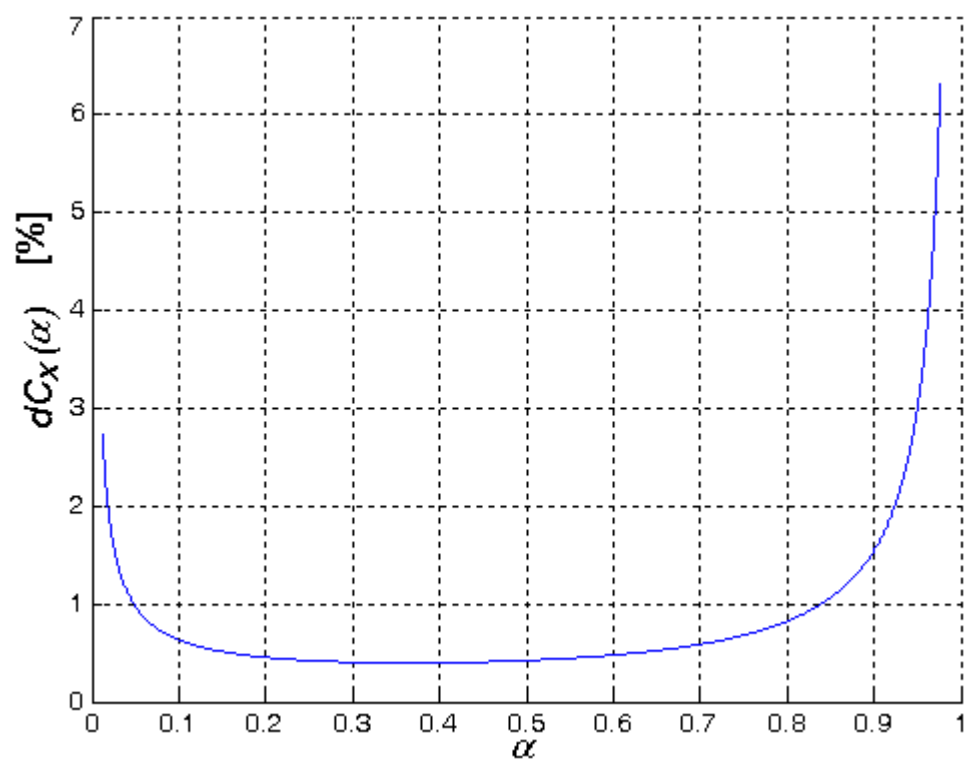


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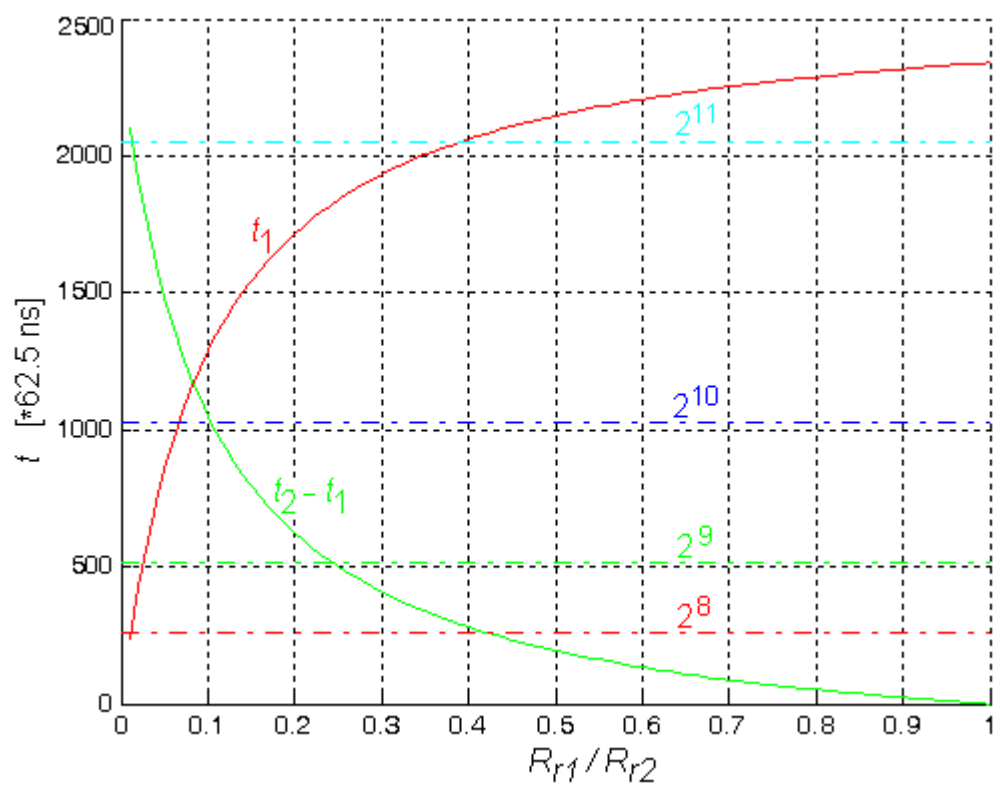


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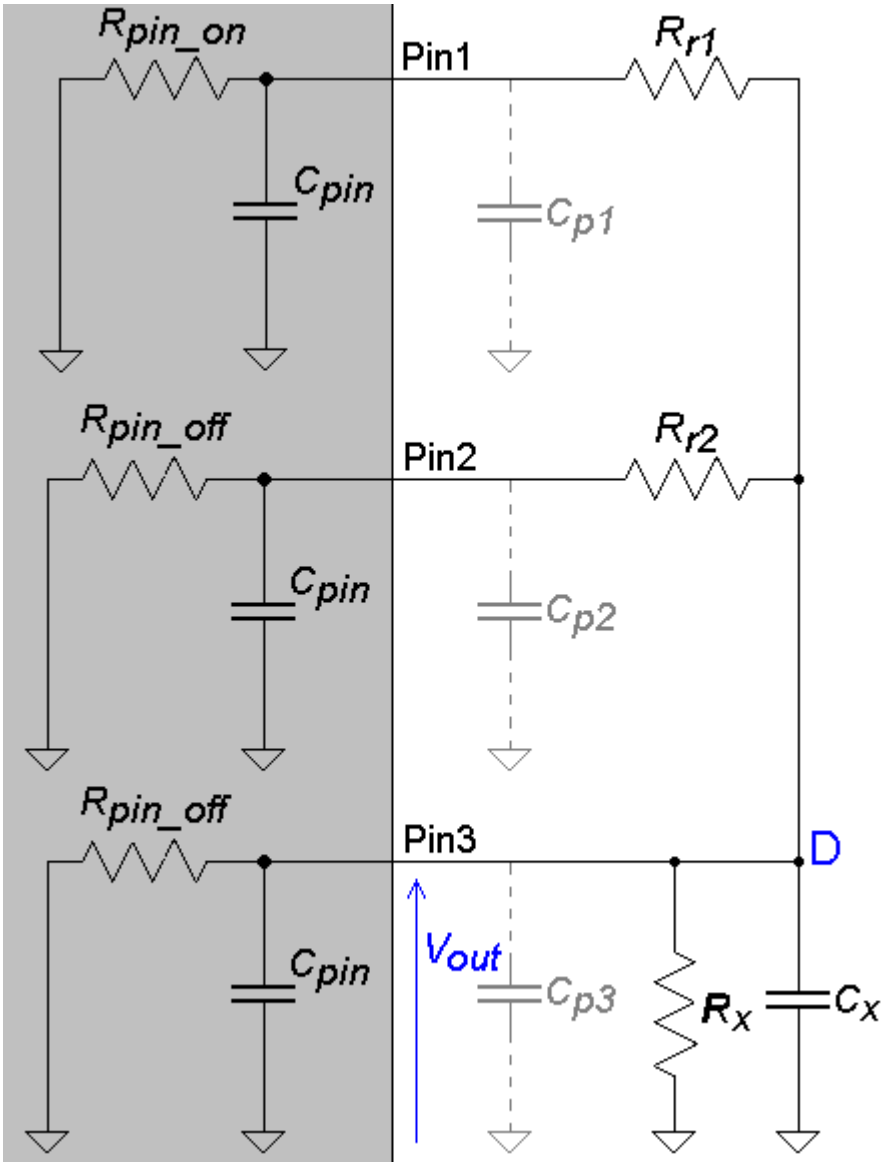


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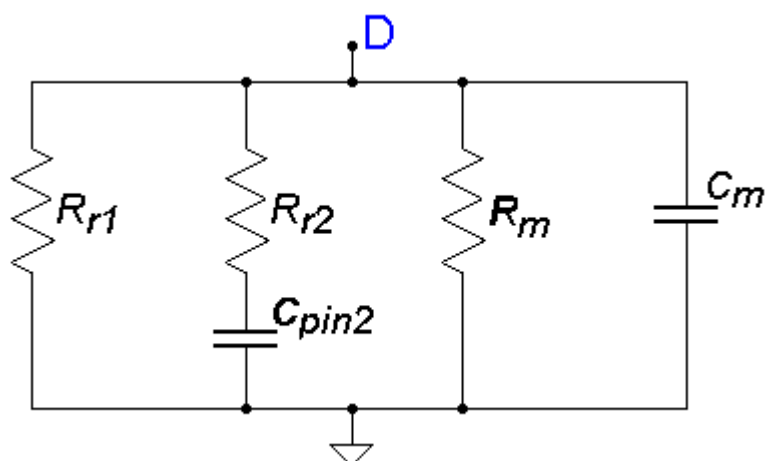




Figure 9

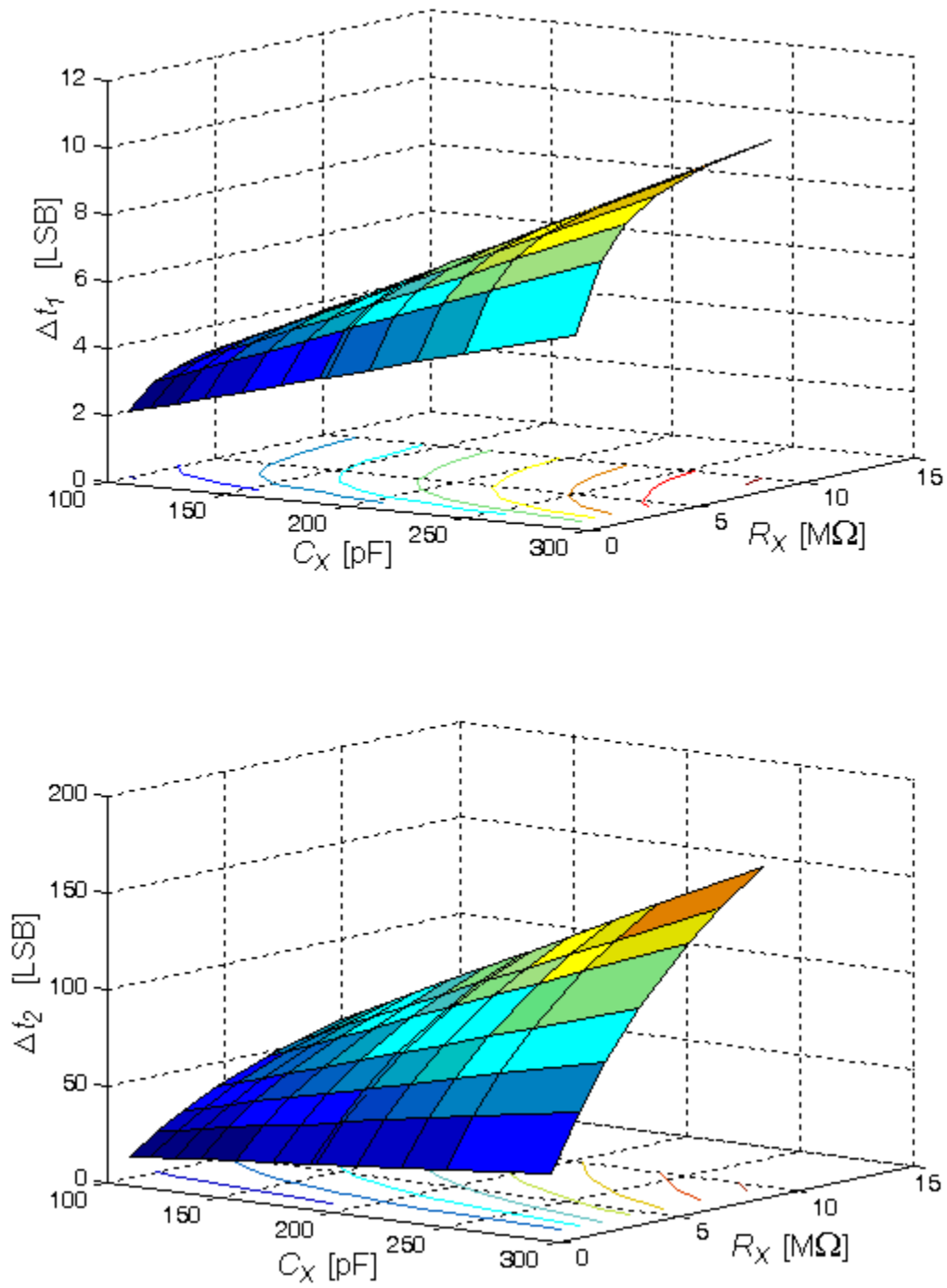


Figure 10

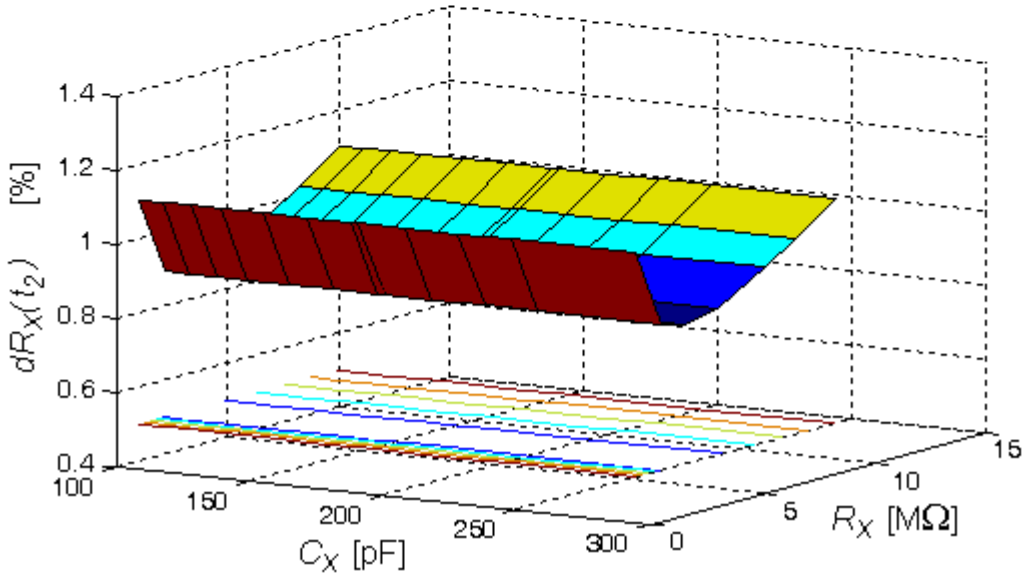
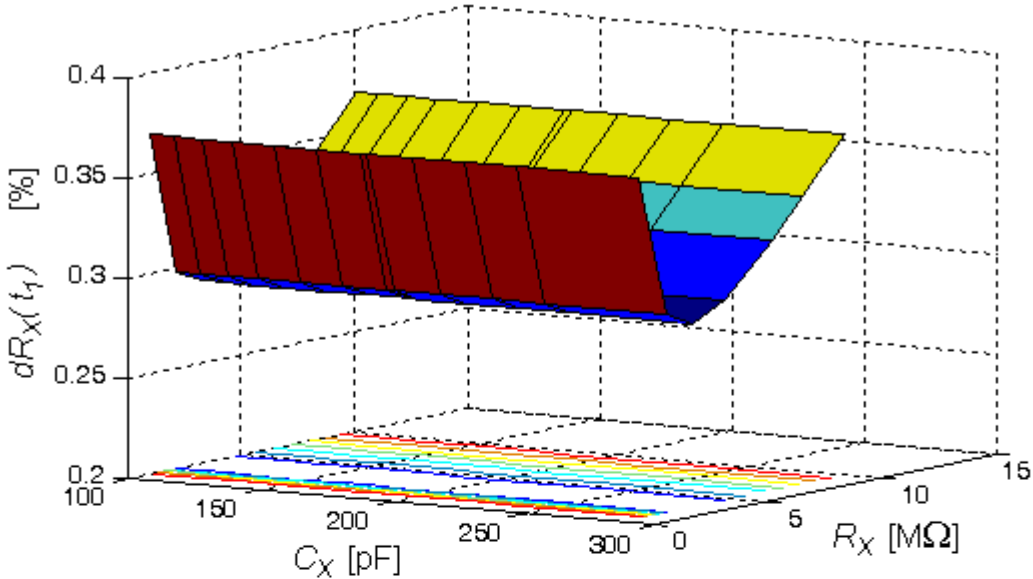


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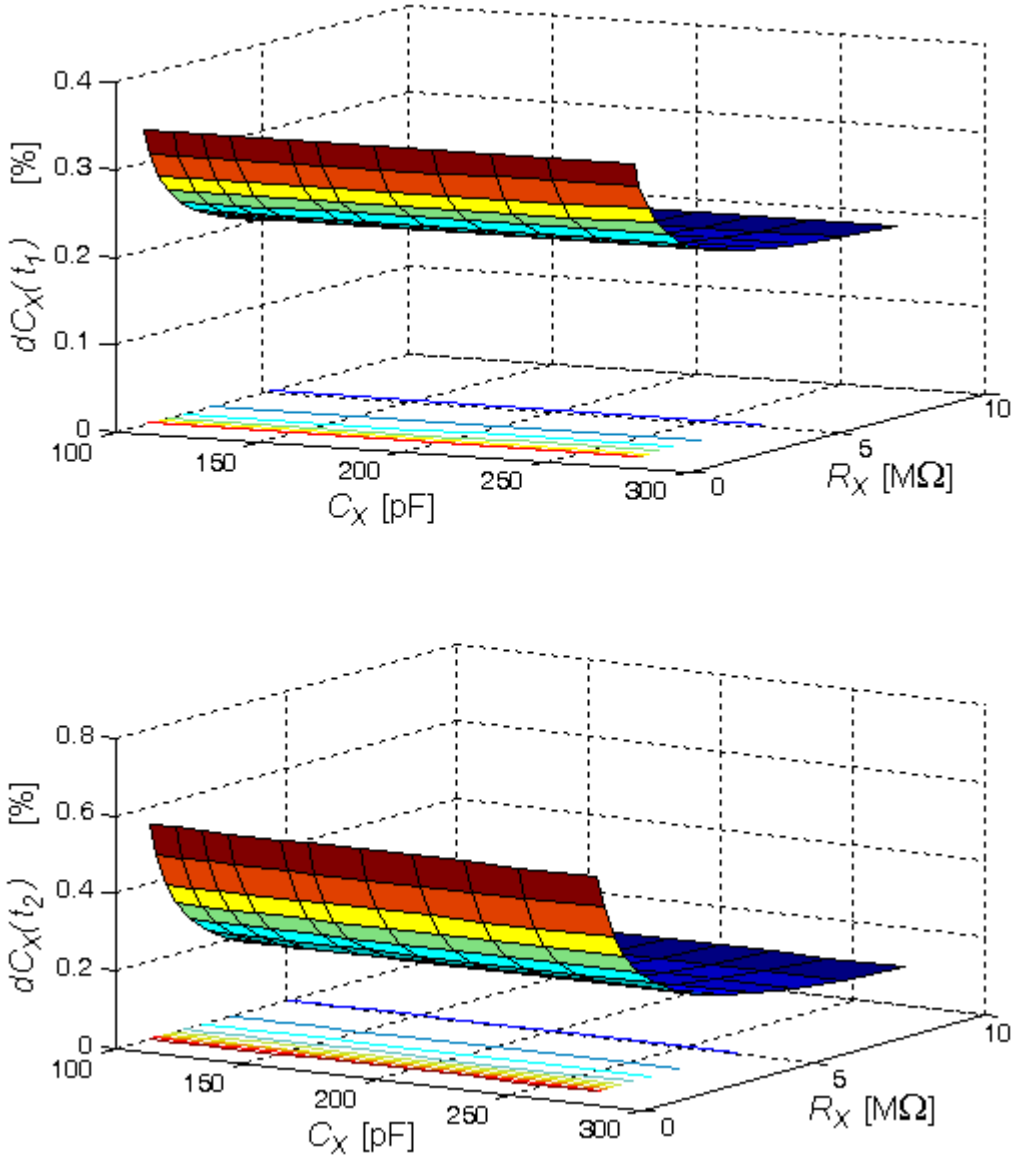


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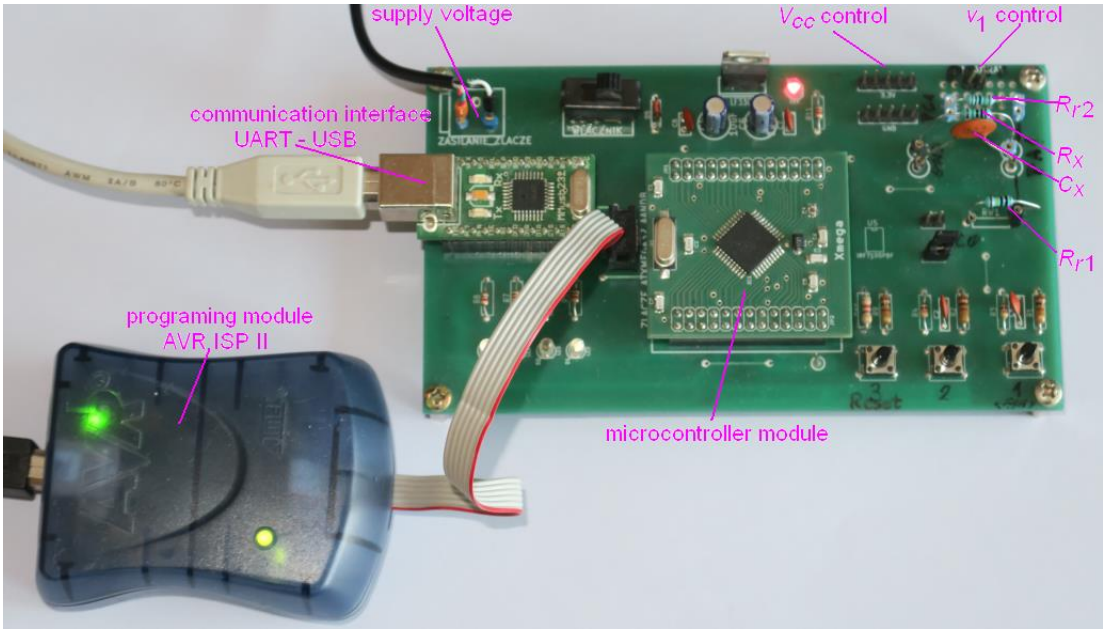


Figure 13

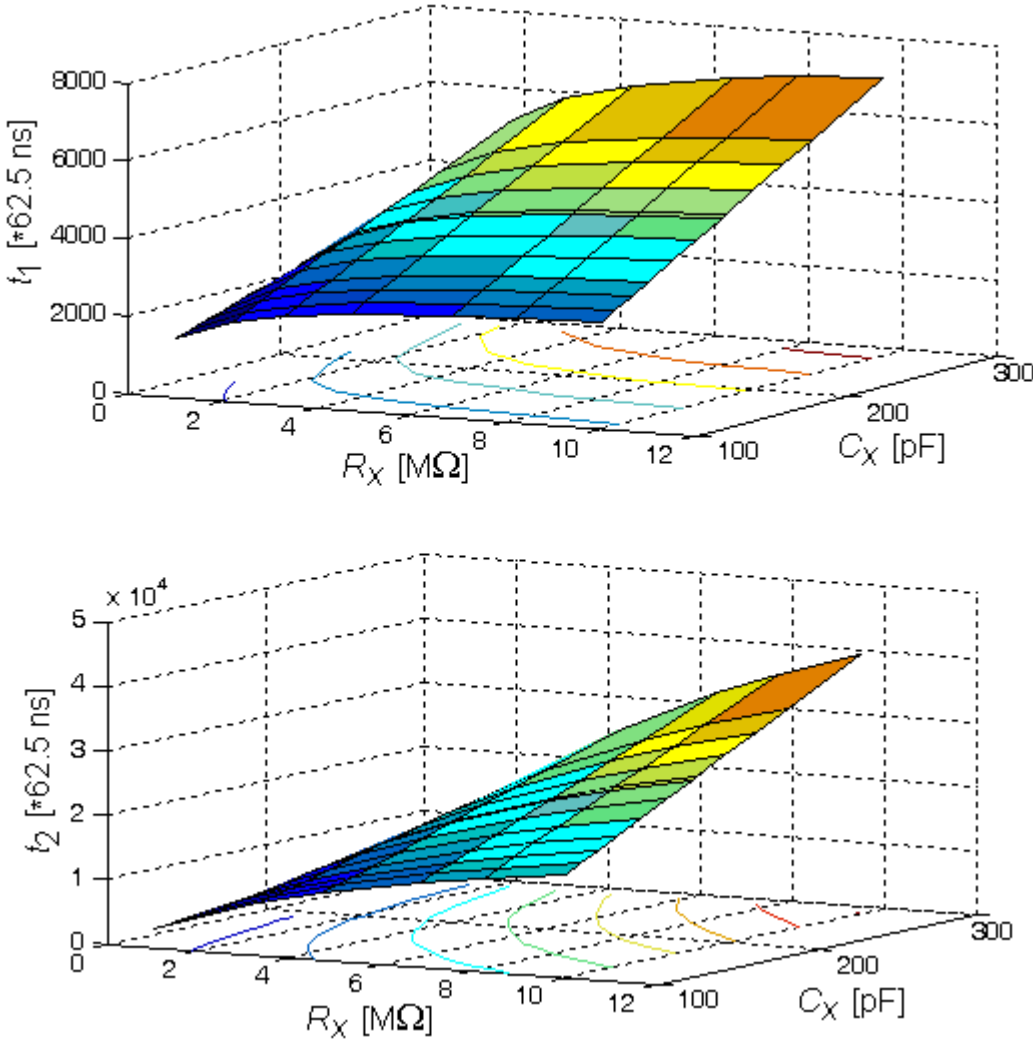


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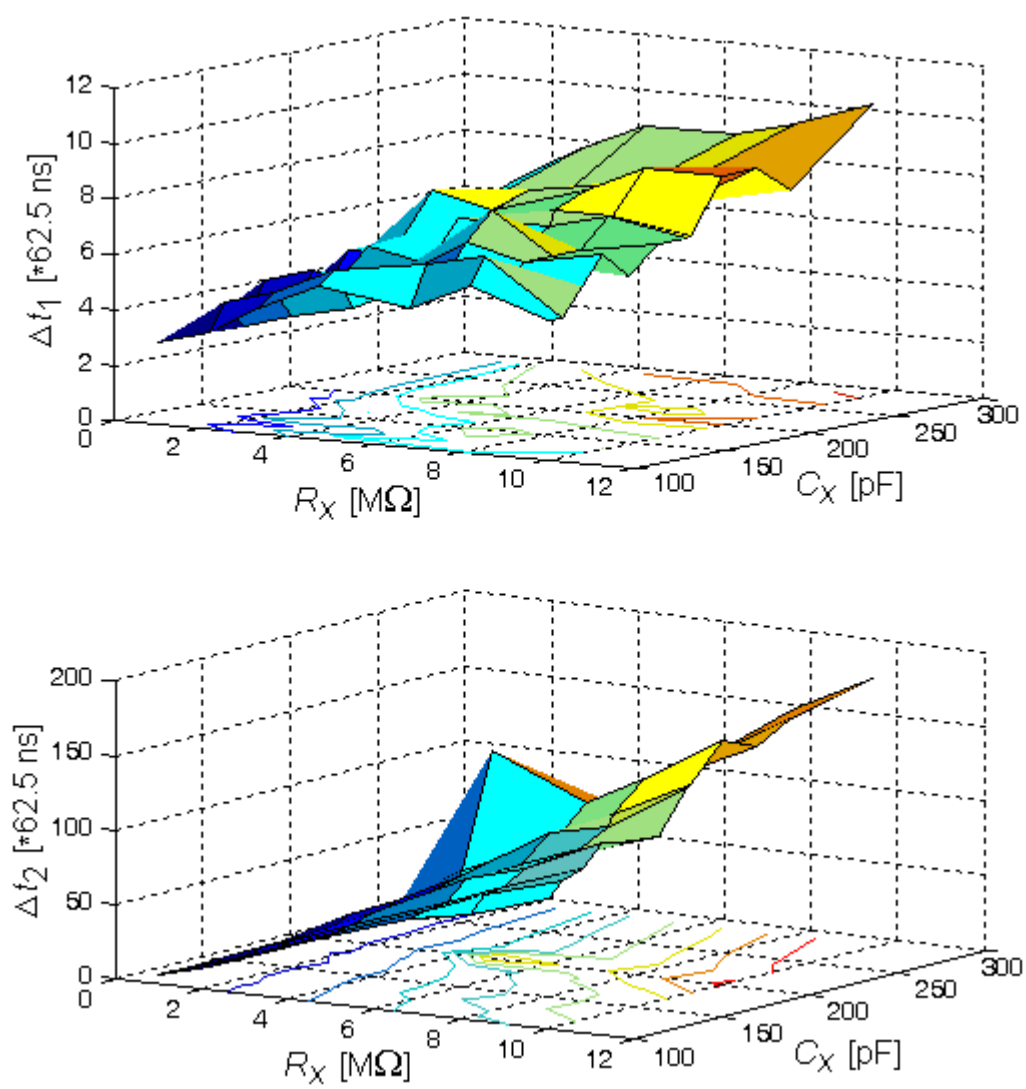


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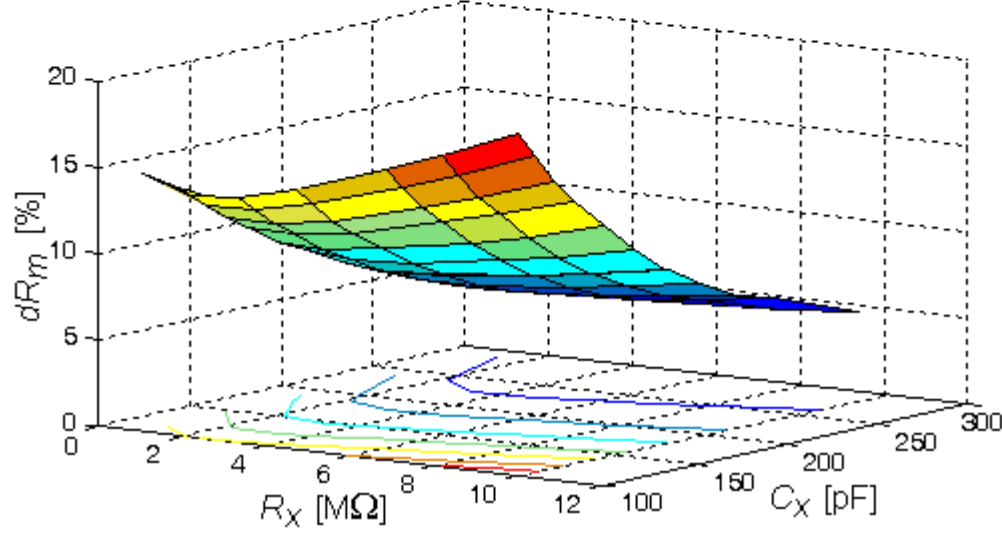
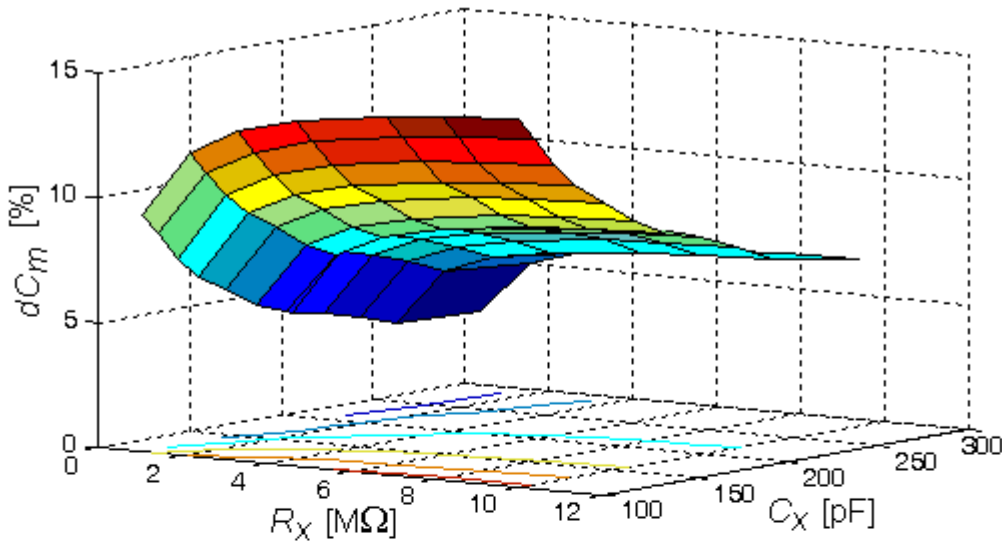


Figure 16

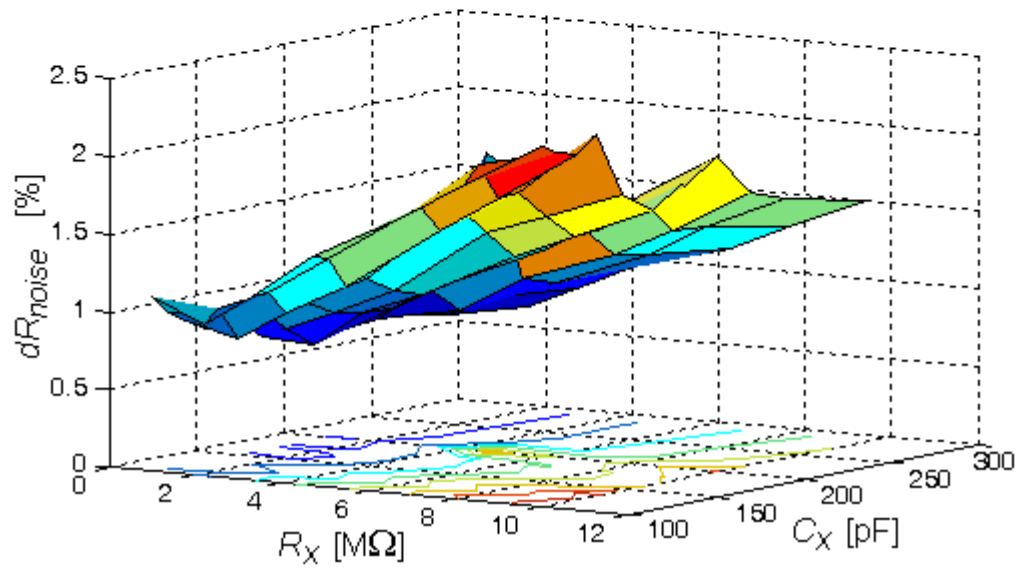
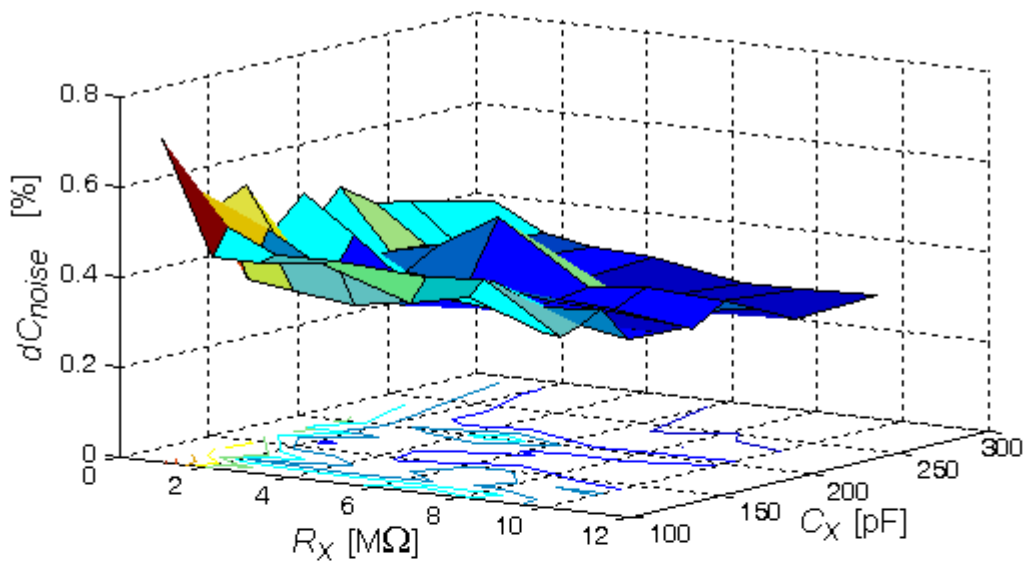




Figure 17

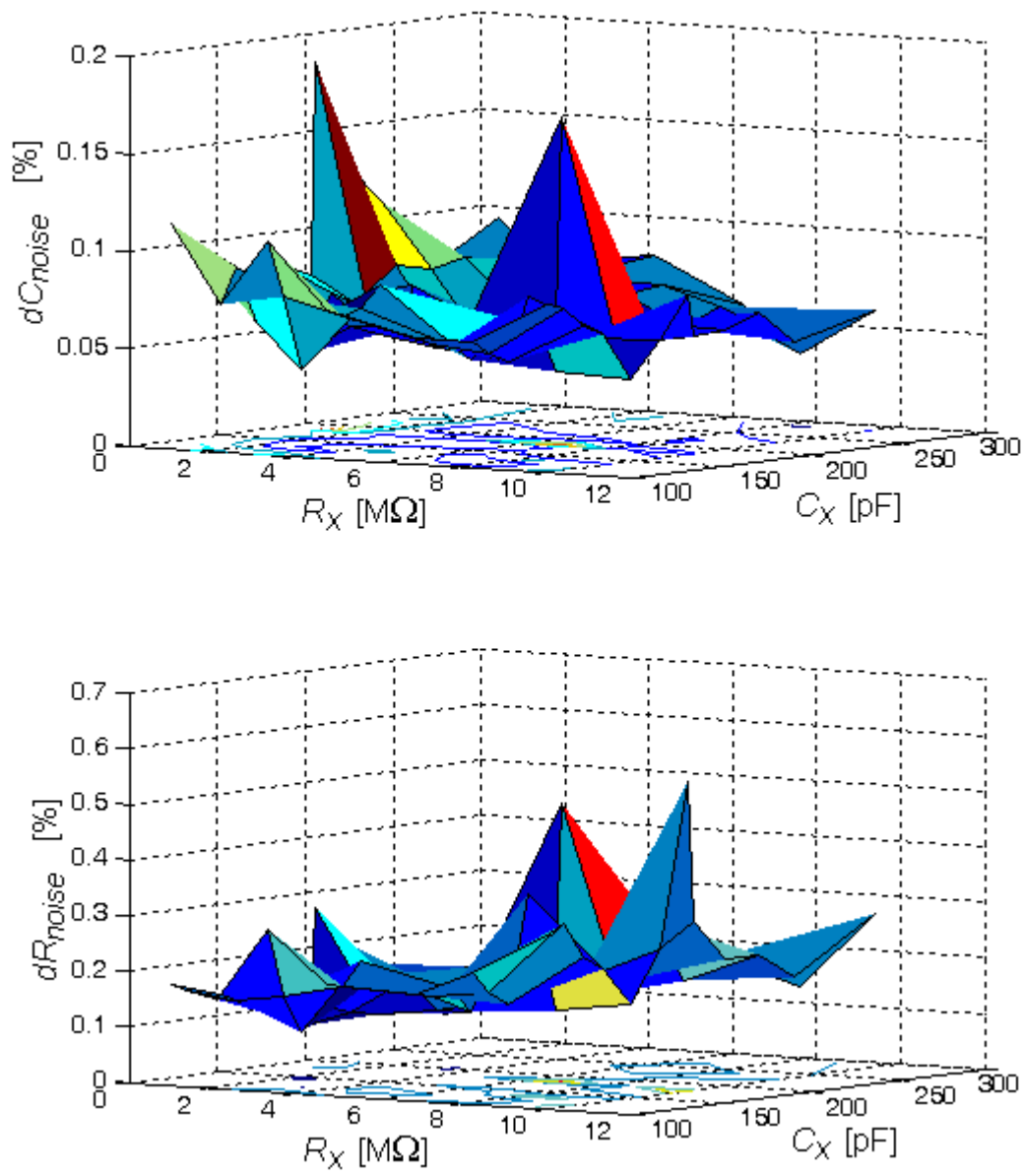


Figure 18

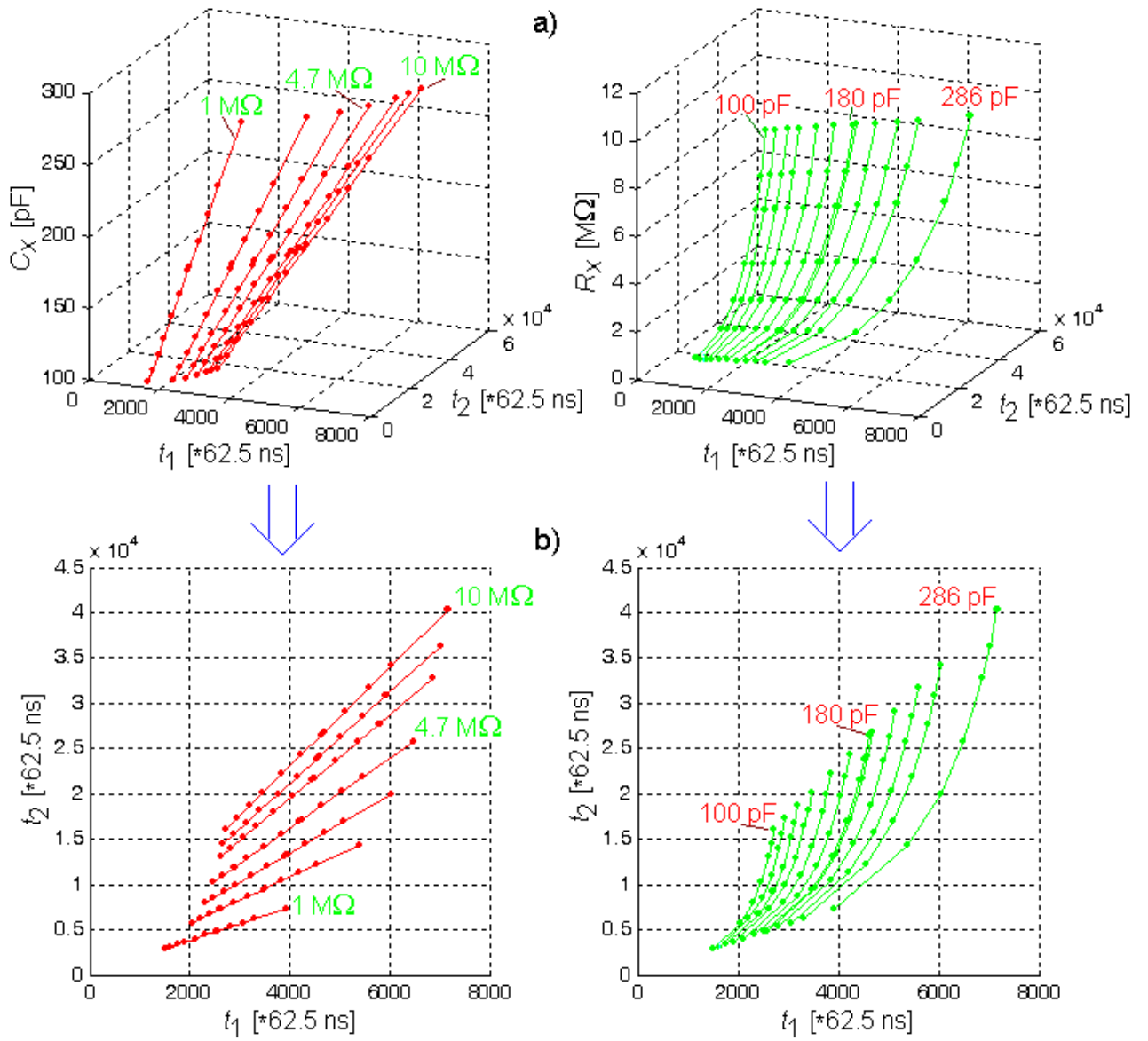


Figure 19

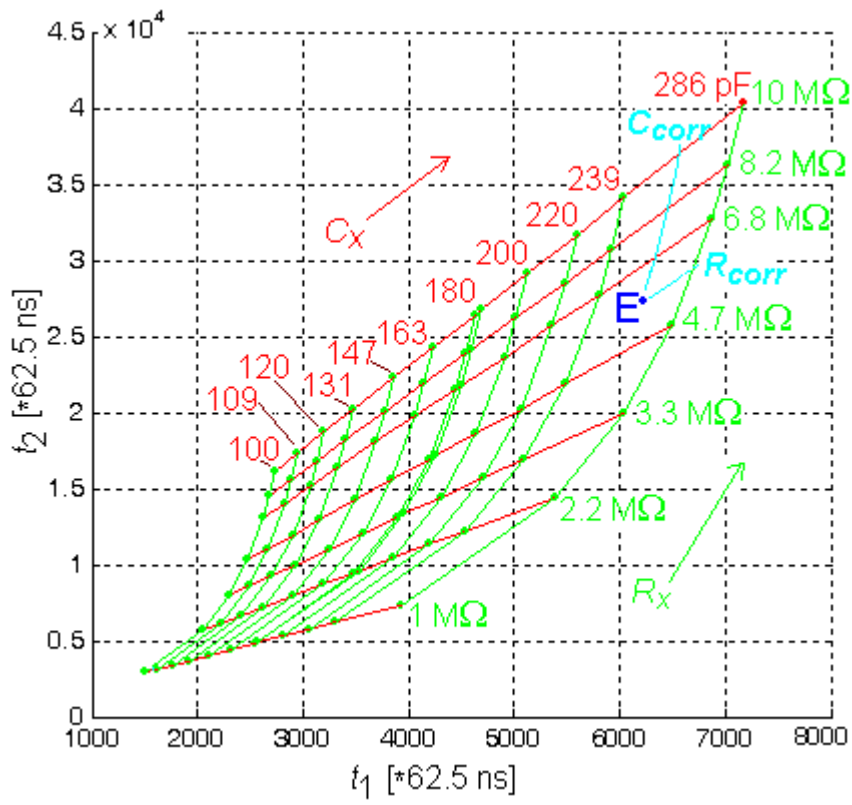


Figure 20

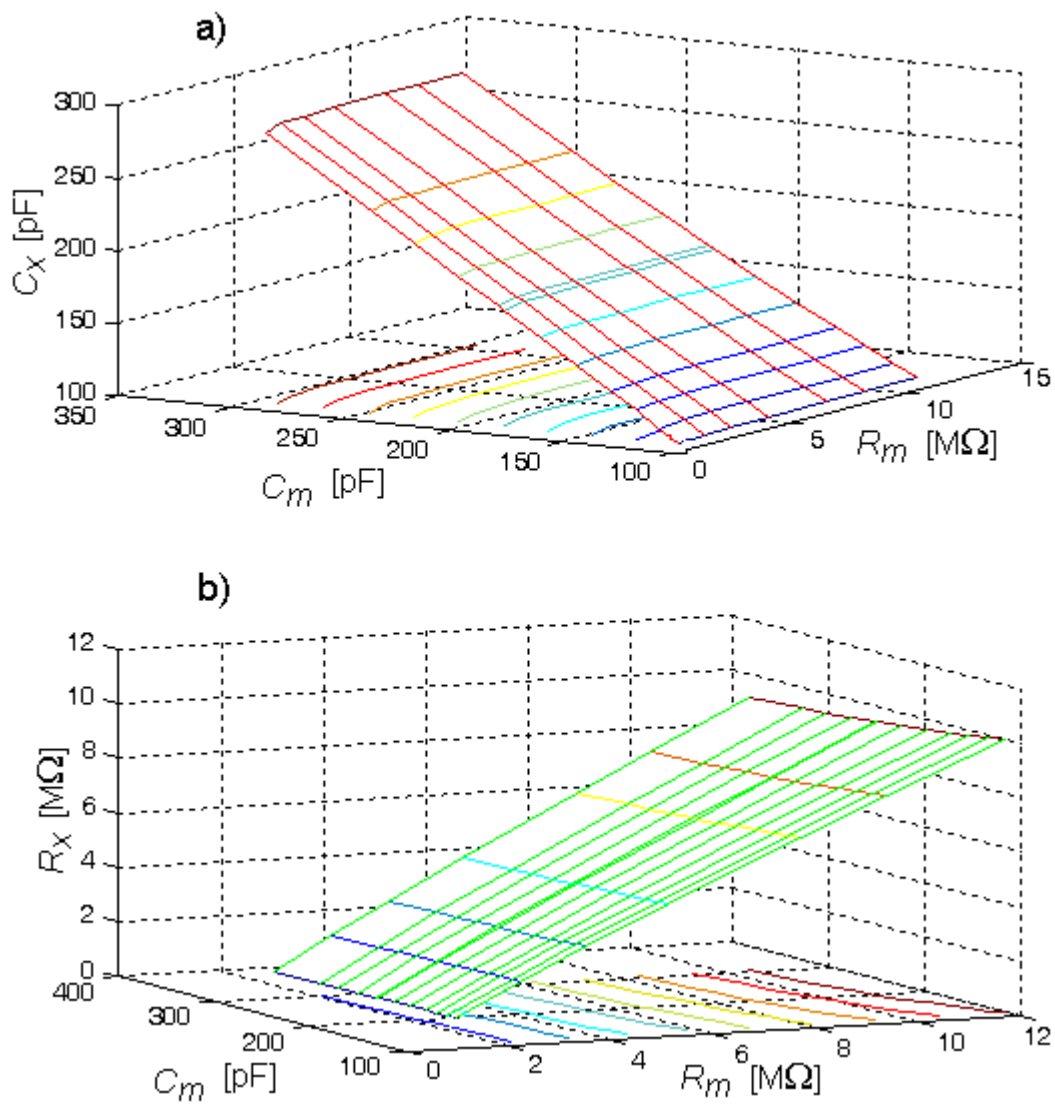


Figure 21

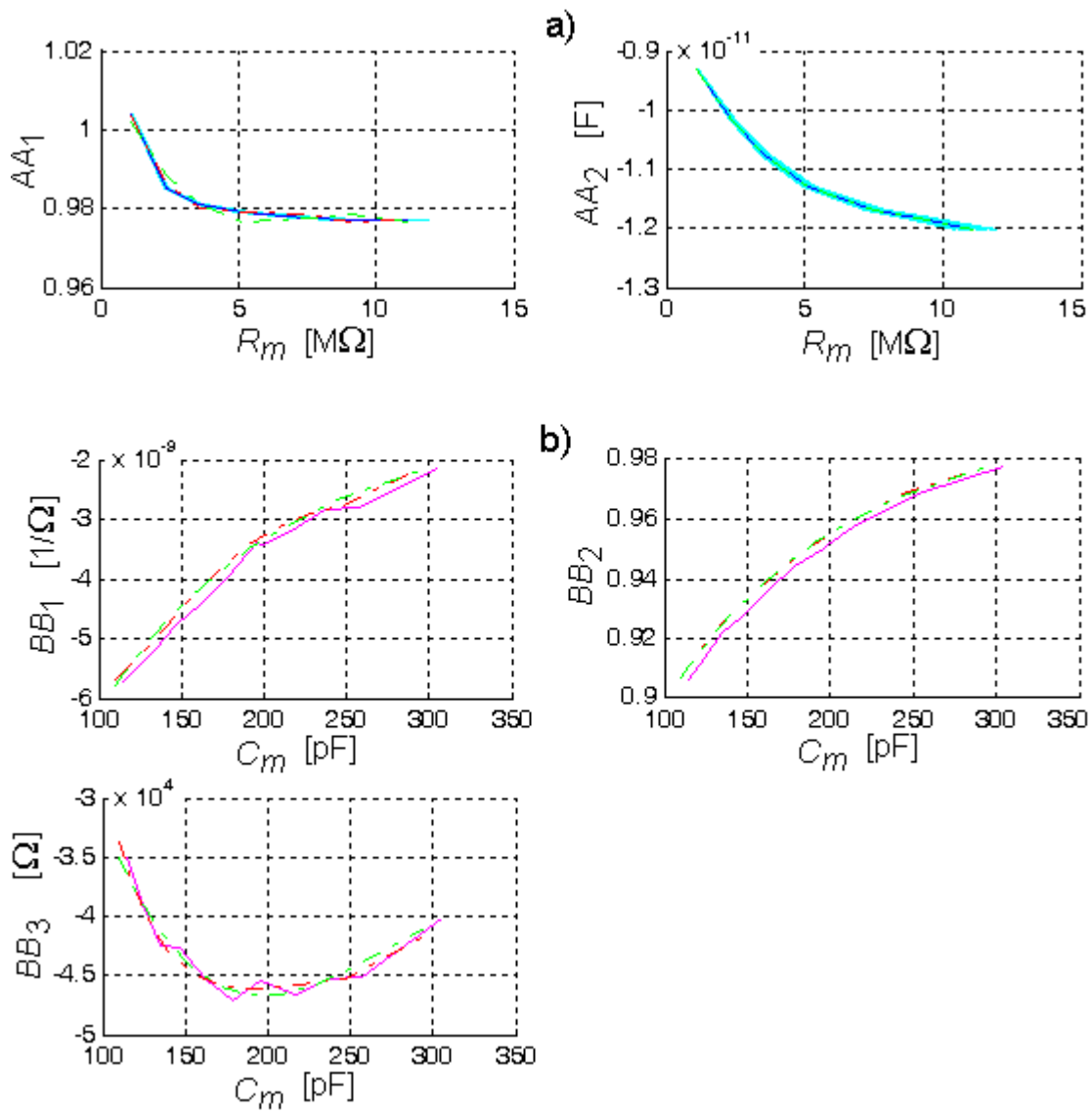


Figure 22

